



IEEE  
Magnetics  
Society

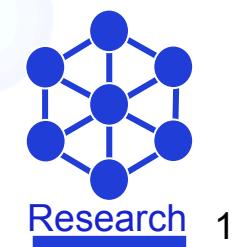
IEEE

## *Distinguished Lecturer Program*

# *Advanced Spintronic Materials: for Generation and Control of Spin Current*

Koki Takanashi

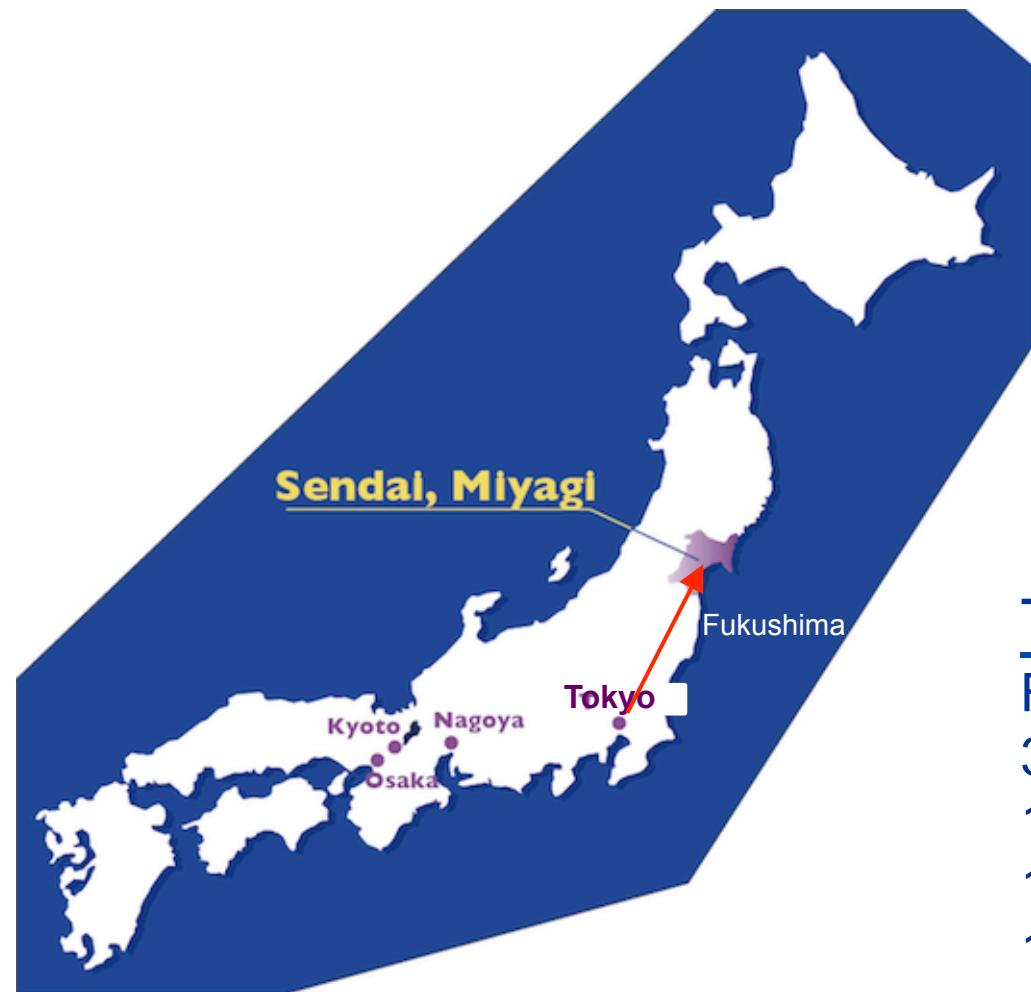
Magnetic Materials Laboratory  
Institute for Materials Research (IMR)  
Tohoku University  
Sendai, Japan





- **IEEE Magnetics Society Home Page:** [www.ieeemagnetics.org](http://www.ieeemagnetics.org)
  - 3000 full members
  - 300 student members
- **The Society**
  - Conference organization (INTERMAG, MMM, TMRC, etc.)
  - Student support for conferences
  - Large conference discounts for members
  - Graduate Student Summer Schools
  - Local chapter activities
  - Distinguished lectures
- ***IEEE Transactions on Magnetics***
  - ~2000 peer reviewed pages each year
  - Electronic access to all *IEEE Transactions on Magnetics* papers
- **Online applications for IEEE membership:** [www.ieee.org/join](http://www.ieee.org/join)
  - 360,000 members
  - IEEE student membership      IEEE full membership

# Where is Tohoku University / Sendai?



## Sendai

1 million population  
350 km north from Tokyo  
~2 h ride by “Shinkansen”  
super-express

## Tohoku University

Founded in 1907  
3,000 Research/Education Staffs  
16,000 Students  
10 Faculties  
18 Graduate Schools  
6 Research Institutes



*Founded in 1907*

# 東北大學・金屬材料研究所

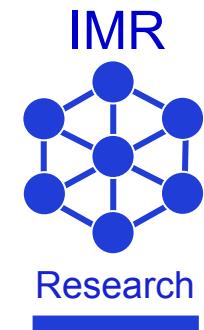
***Institute for Materials Research (IMR)***  
***Tohoku University***



**Kotaro Honda**  
1<sup>st</sup> Director  
KS magnet (1917)

**Honda Memorial Hall**

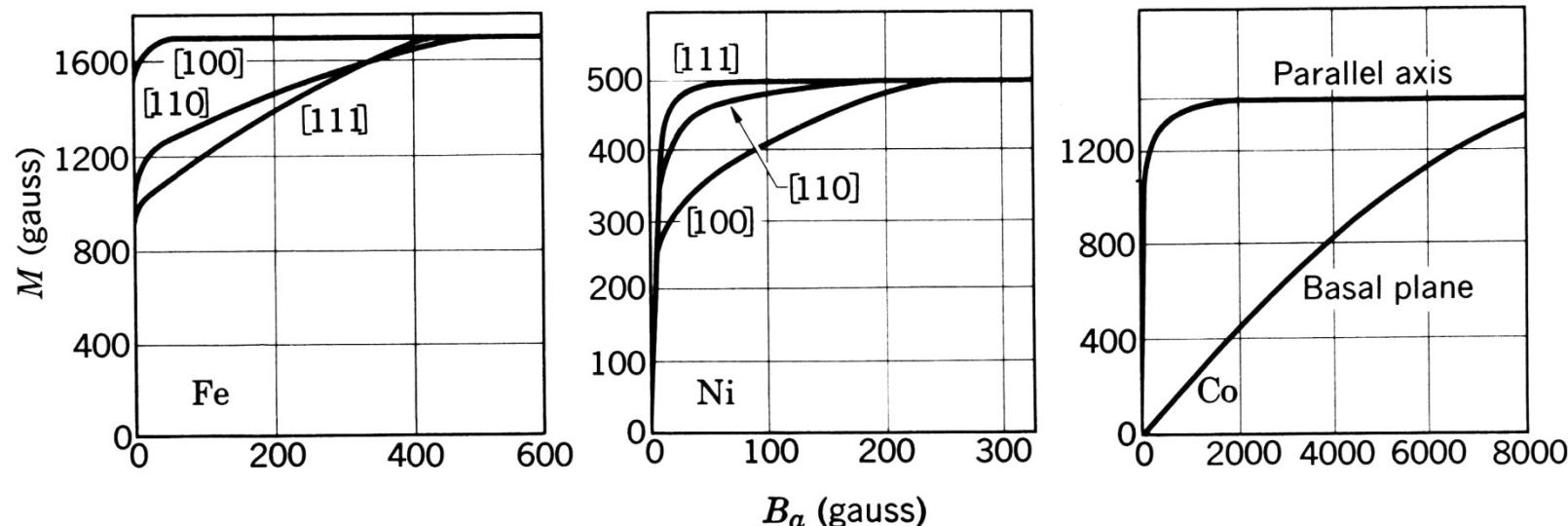
***KIN KEN***



*Founded in 1916*

*We will have a  
centennial anniversary  
in 2016!*

# First experimental evidence for magnetocrystalline anisotropy



**Figure 30** Magnetization curves for single crystals of iron, nickel, and cobalt. From the curves for iron we see that the [100] directions are easy directions of magnetization and the [111] directions are hard directions. The applied field is  $B_a$ . (After Honda and Kaya.)

→ *Sci. Rep. Tohoku Imperial Univ. 15, 721 (1926).*

*C. Kittel, “Introduction to Solid State Physics”*



*Founded in 1907*

# 東北大學・金屬材料研究所

***Institute for Materials Research (IMR)***  
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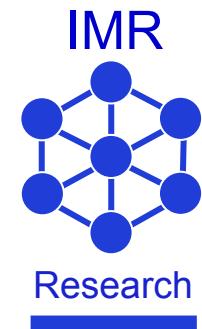
**Kotaro Honda**  
1<sup>st</sup> Director

KS magnet (1917)

President of Tohoku Univ. (1931 – 1940)

**Honda Memorial Hall**

***KIN KEN***



*Founded in 1916*

*We will have a  
centennial anniversary  
in 2016!*

*Presently,  
120 Research Staffs  
200 Students  
27 Laboratories  
9 Research Centers*

# Magnetic Materials Laboratory (2012-2013)

## Lab members

Professor Koki Takanashi  
Assoc. Prof. Masaki Mizuguchi  
Assist. Prof. Yuya Sakuraba (~March 2013)  
Takeshi Seki  
Takahide Kubota (April 2013~)  
Post-doc. Bosu Subrojati (Bangladesh)  
Takayuki Kojima  
Hitomi Yako  
DC student Wei-Nan Zhou (China)  
Jinhyeok Kim (Korea)  
+ 8 MC students



*FY 2012*



*FY 2013*

## Collaborators

Seiji Mitani (NIMS, Tsukuba)  
Toshiyuki Shima (Tohoku-gakuin Univ.)  
Masato Kotsugi (Spring-8)  
Sadamichi Maekawa, Eiji Saitoh, Gerrit Bauer (JAEA / IMR, Tohoku Univ.)  
Masafumi Shirai (RIEC, Tohoku Univ.), Shigemi Mizukami (WPI, Tohoku Univ.)  
Yasuo Ando, Junsaku Nitta (Faculty of Engng., Tohoku Univ.)

# Outline

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## 1. Introduction

What is **spin current**?

Relationship between **spin current** and **spintronics**

Historical background: GMR

## 2. Recent progress in research

on **pure spin current**

Spin Hall effect / spin pumping / spin Seebeck effect

## 3. Topics of materials for spintronics

Highly spin-polarized: half-metallic Heusler alloys

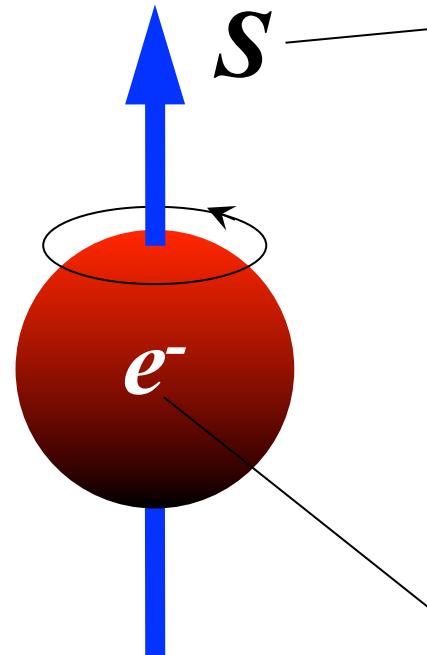
Perpendicularly spin-polarized:

high magnetic anisotropy  $L1_0$ -ordered alloys

## 4. Summary

# What is spin current ?

Angular momentum



Electron

*not conserved*

Spin

Origin of  
magnetism



**Spin current**

A concept that has attracted  
much attention in recent years

$$J_s = J_{\uparrow} - J_{\downarrow}$$

*conserved*

Charge

Origin of  
electricity

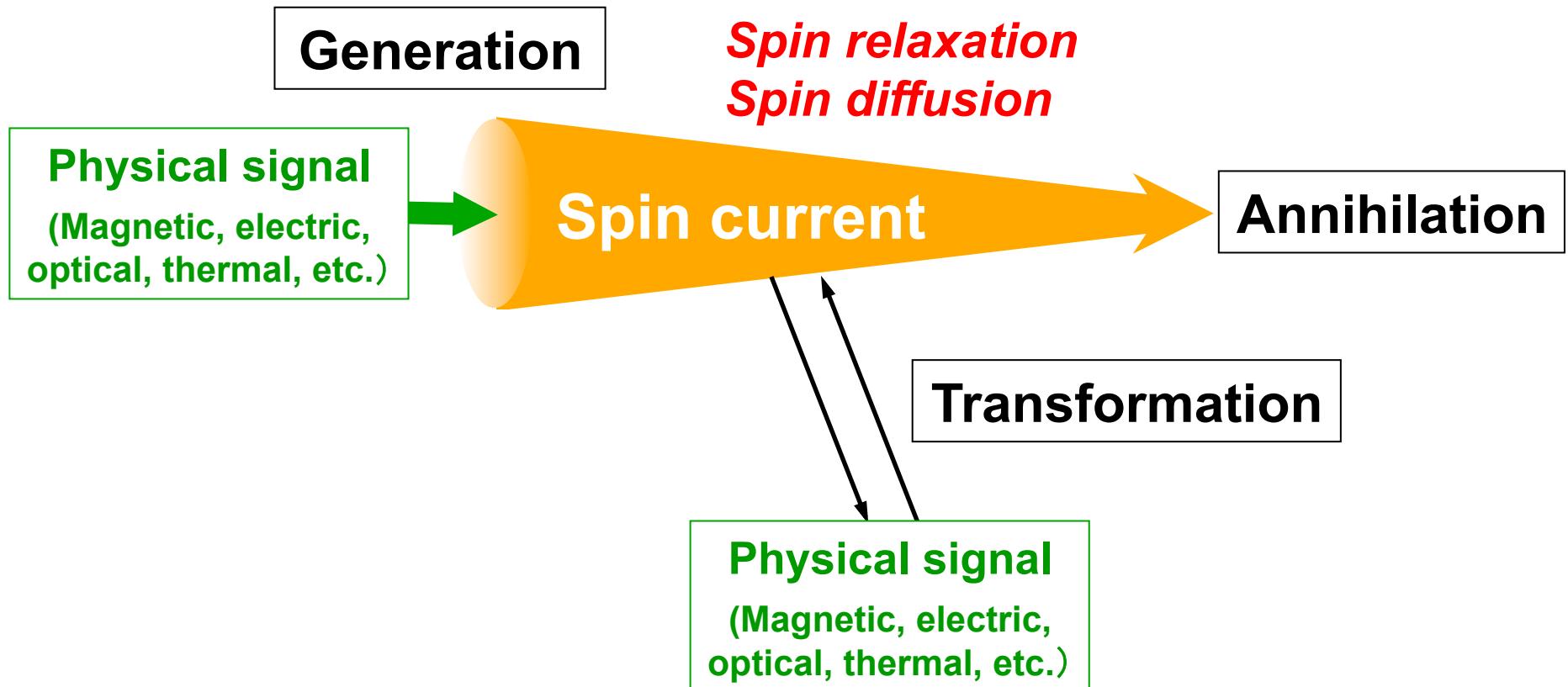


Electric current

A lot of studies since the 18<sup>th</sup> C.  
Indispensable in daily life

$$J_e = J_{\uparrow} + J_{\downarrow}$$

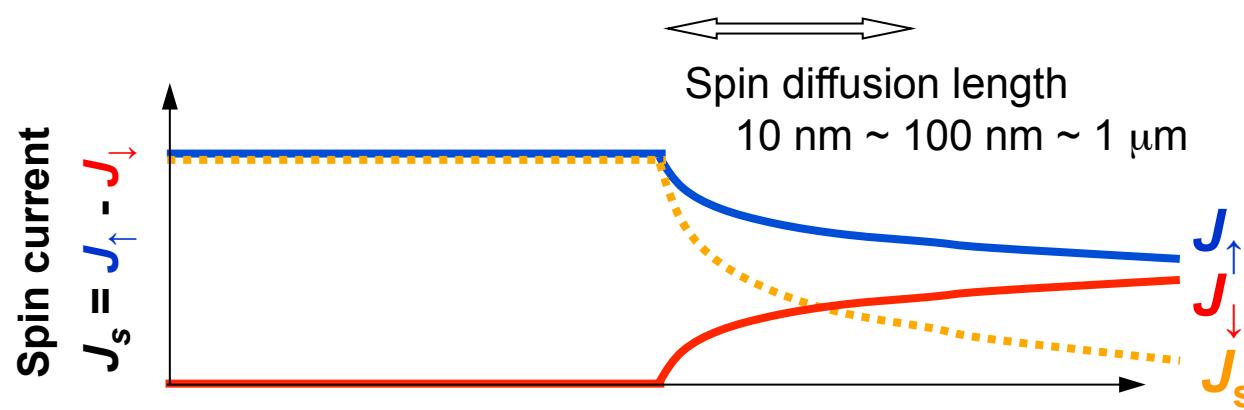
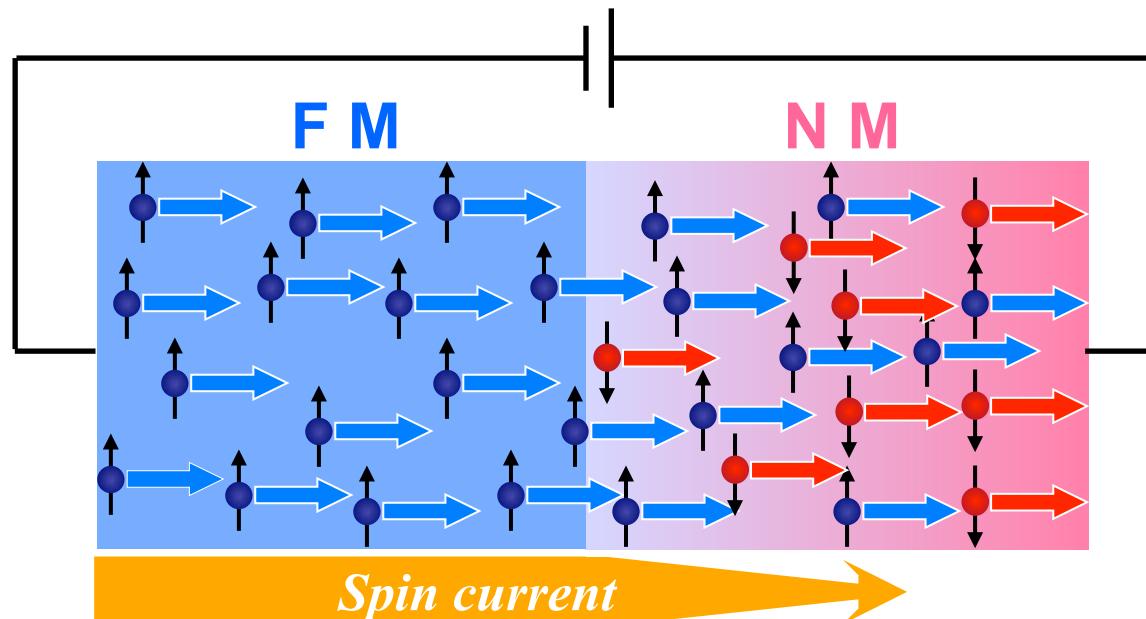
# What is spin current ?



# Example of spin current -1

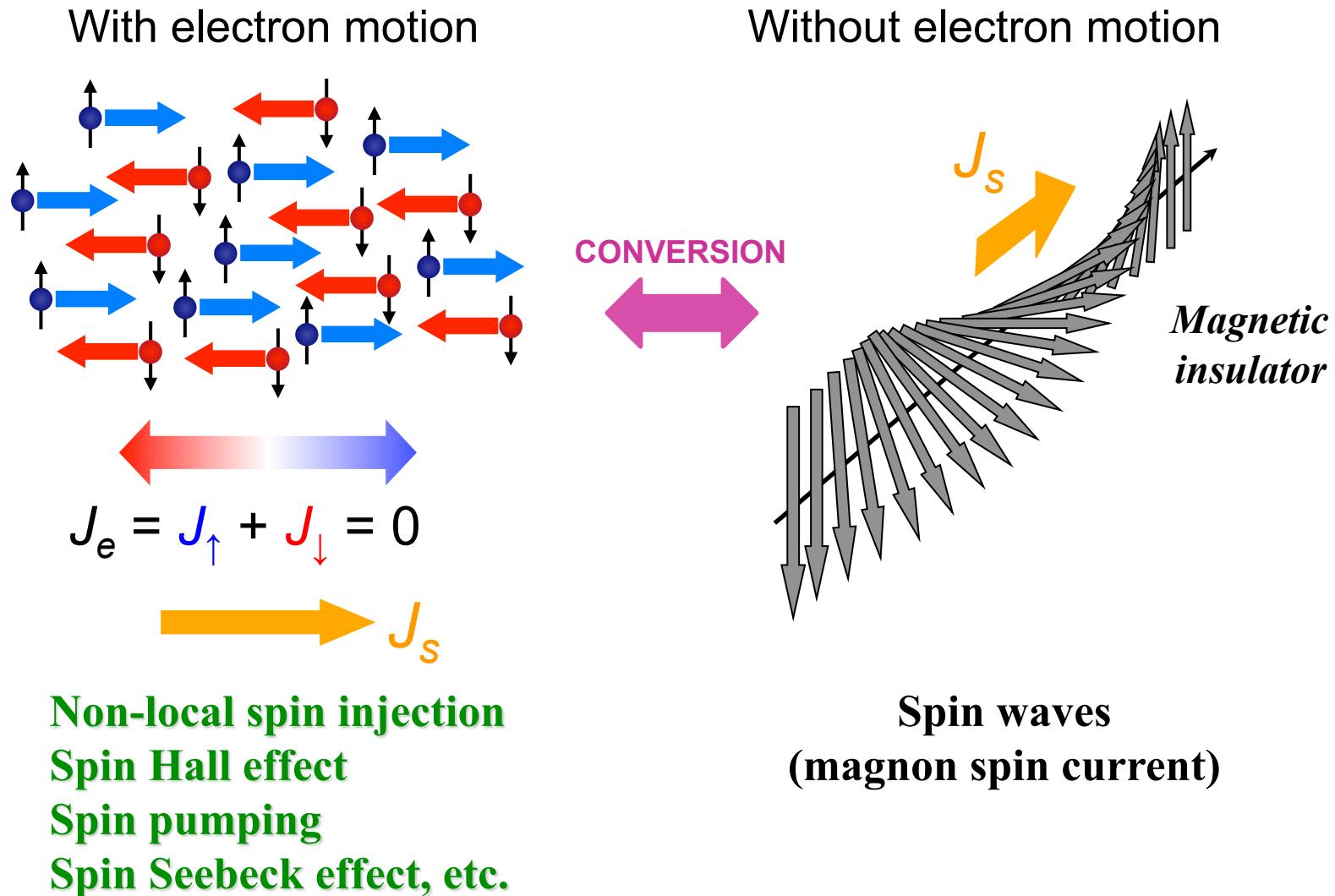
- With electric current

Electrical *spin injection* from ferromagnetic material (FM) into nonmagnetic material (NM)



## Example of spin current -2

- Without electric current (pure spin current)

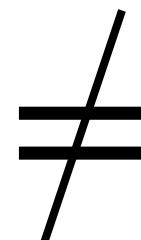


# **Feature of spin current**

*For electric current*

Conductor  
(metal/semiconductor)

Insulator



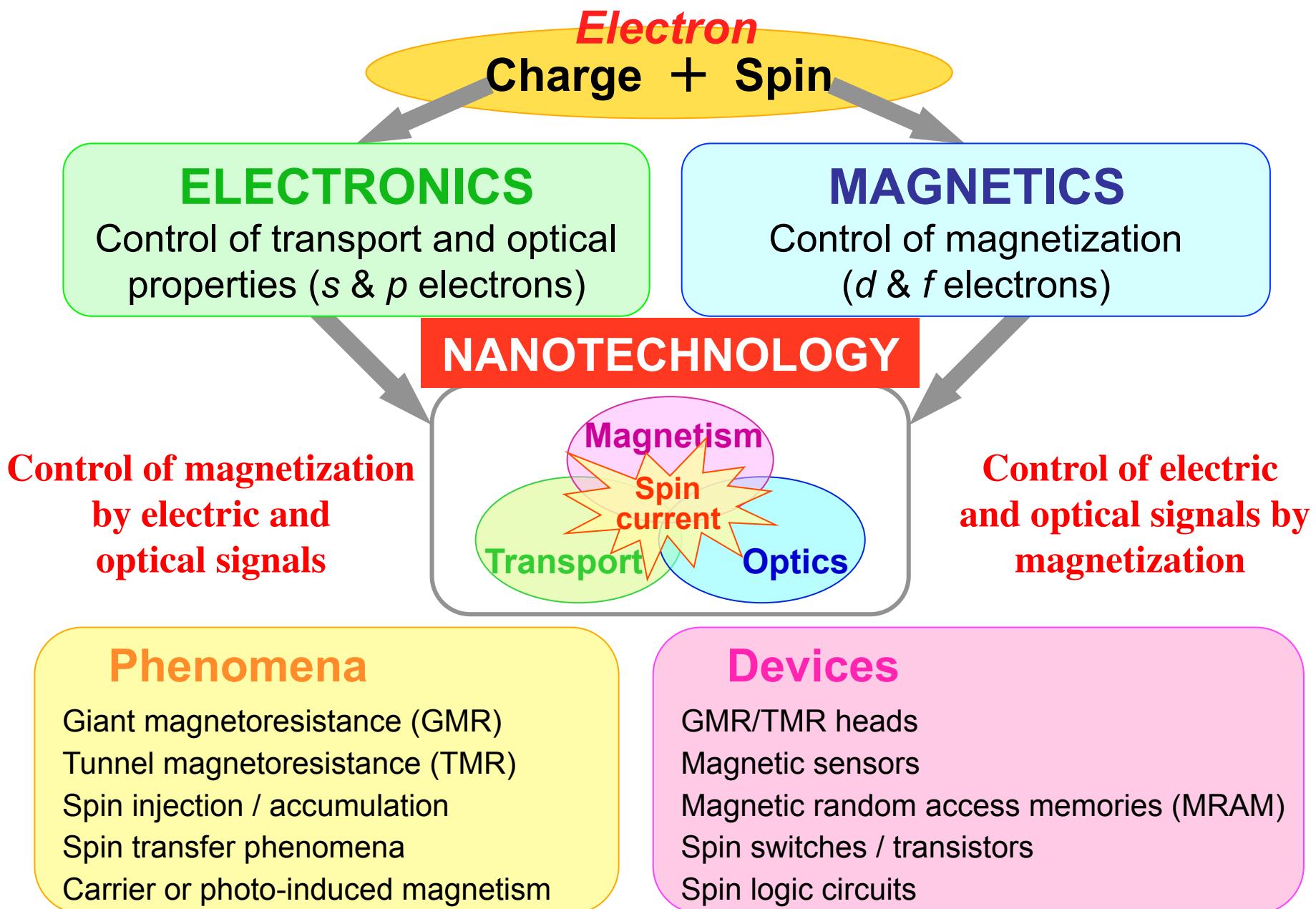
*For spin current*

Conductor

Insulator

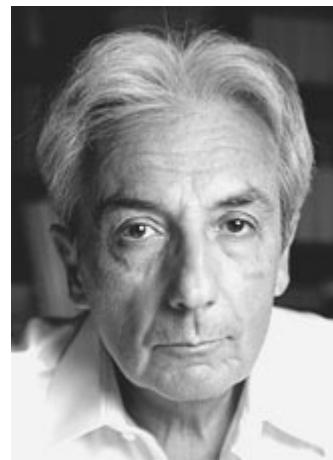
**Spin current may flow in an electric insulator.**

# What is spintronics ?

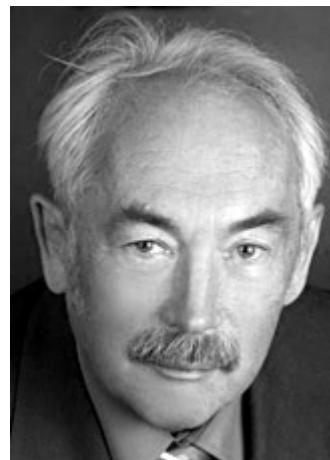


# Nobel prize in physics 2007

Albert Fert  
(France)



Peter Grünberg  
(Germany)



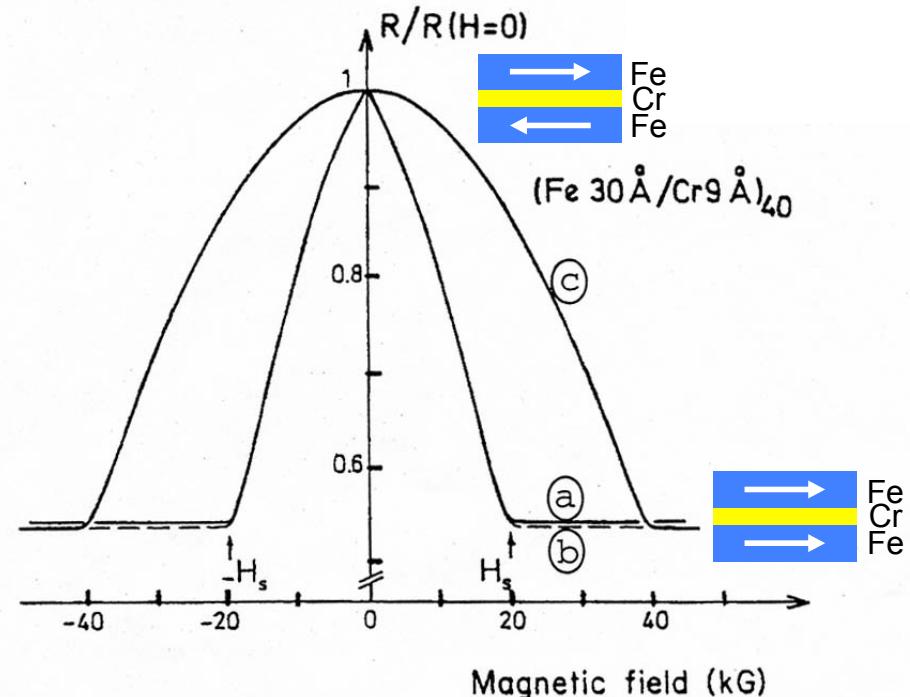
**Discovery of GMR**



**Remarkable enhancement of recording density of HDD**

**“The first major application of nanotechnology”**

**Development of spintronics**



M. N. Baibich *et al.*, Phys. Rev. Lett., **61** (1988) 2472.

## Giant Magnetoresistance (GMR)

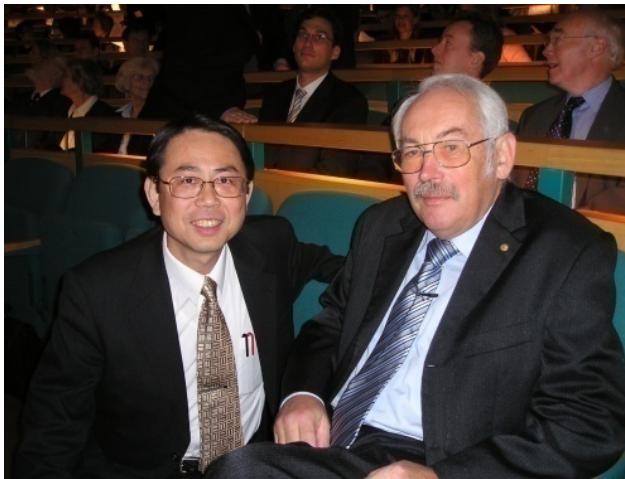
Large difference in electrical resistance between parallel and antiparallel alignments of magnetization.  
(Spin-dependent transport)

*Principle of spin-valve GMR head*

# **Nobel week in Stockholm, December 2007**



On the Noble lecture (Dec. 8, 2007)



At the award ceremony  
(Dec. 10, 2007)



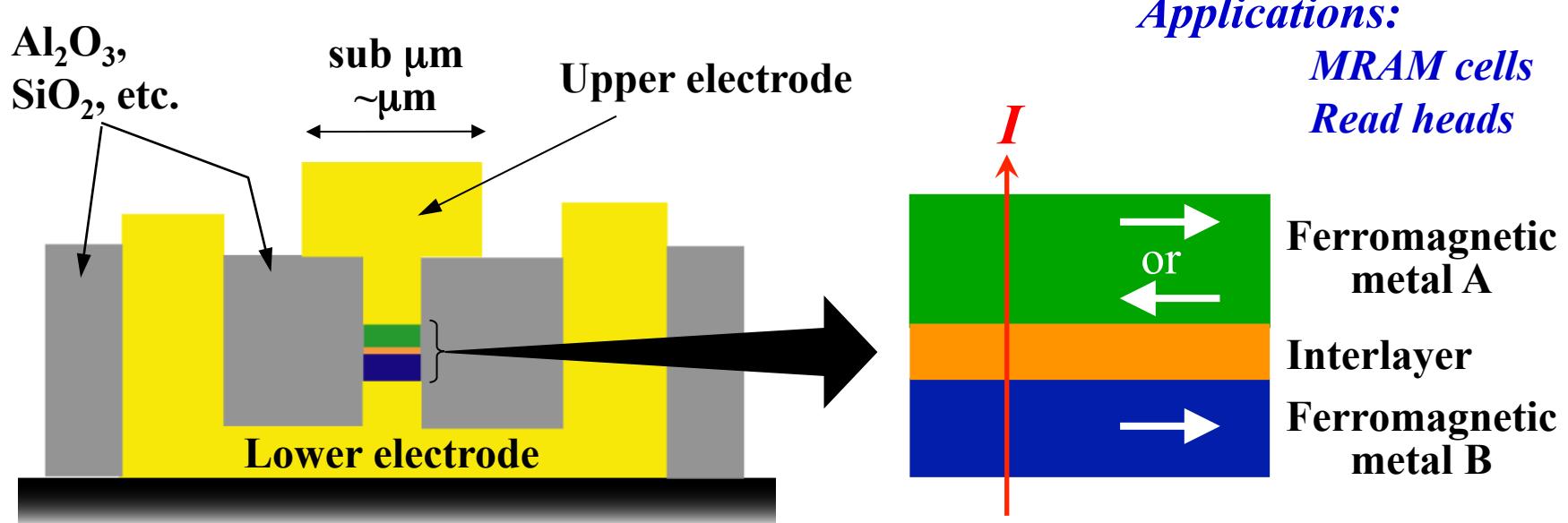
At the Reception by the Royal Swedish Academy  
(Dec. 7, 2007)



At the Nobel banquet  
(Dec. 10, 2007) 16

# Typical device structures in spintronics

## 1. CPP (Current-Perpendicular-to-Plane) type



Interlayer = Insulator: Tunnel magnetoresistance (TMR)

Metal : Giant magnetoresistance (CPP-GMR)

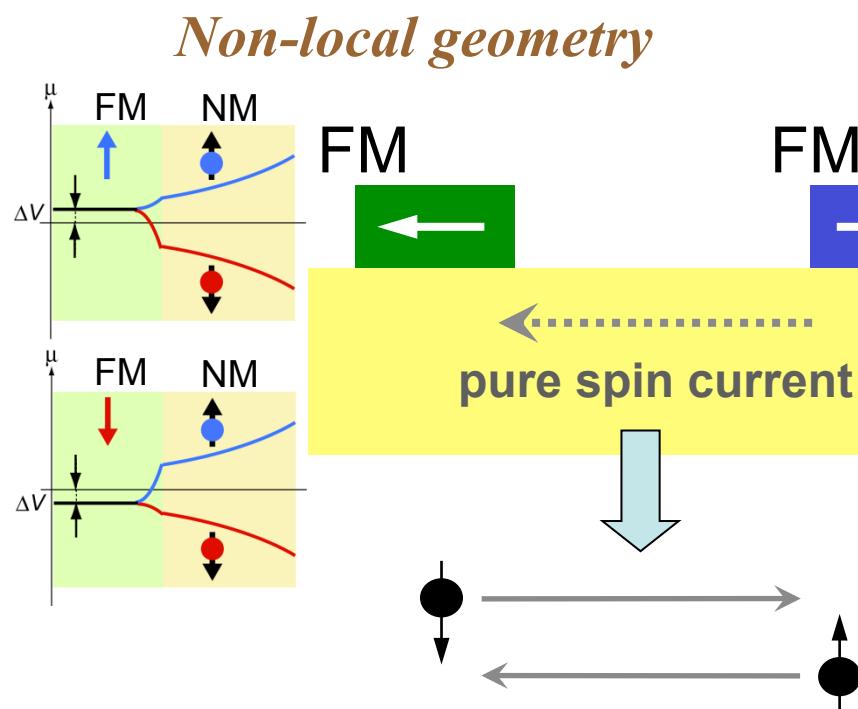
$$\text{Magnitude of MR} : \frac{\Delta R}{R} \propto P_A \cdot P_B$$

$P_{A(B)}$ : spin polarization of conduction electrons in A (B)

# Typical device structures in spintronics

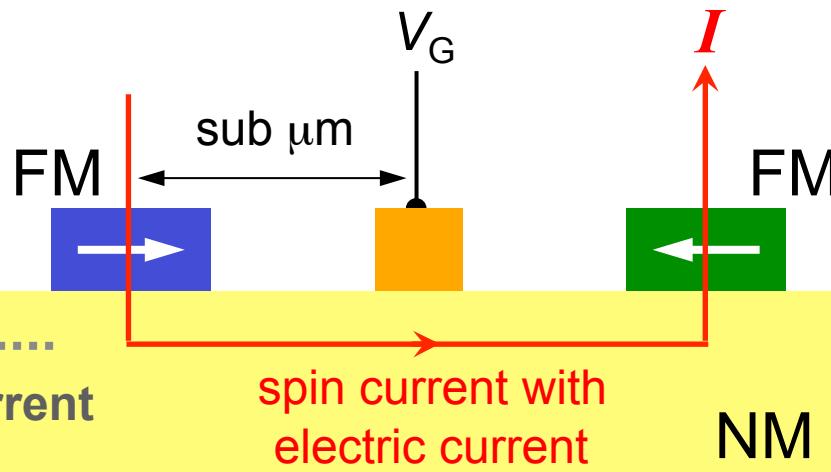
## 2. Lateral structure type

*Applications: spin transistor, etc.*



$$J_e = J_{\uparrow} + J_{\downarrow} = 0$$

$$J_s = J_{\uparrow} - J_{\downarrow} \neq 0$$



*Key: efficiency of  
Spin injection*

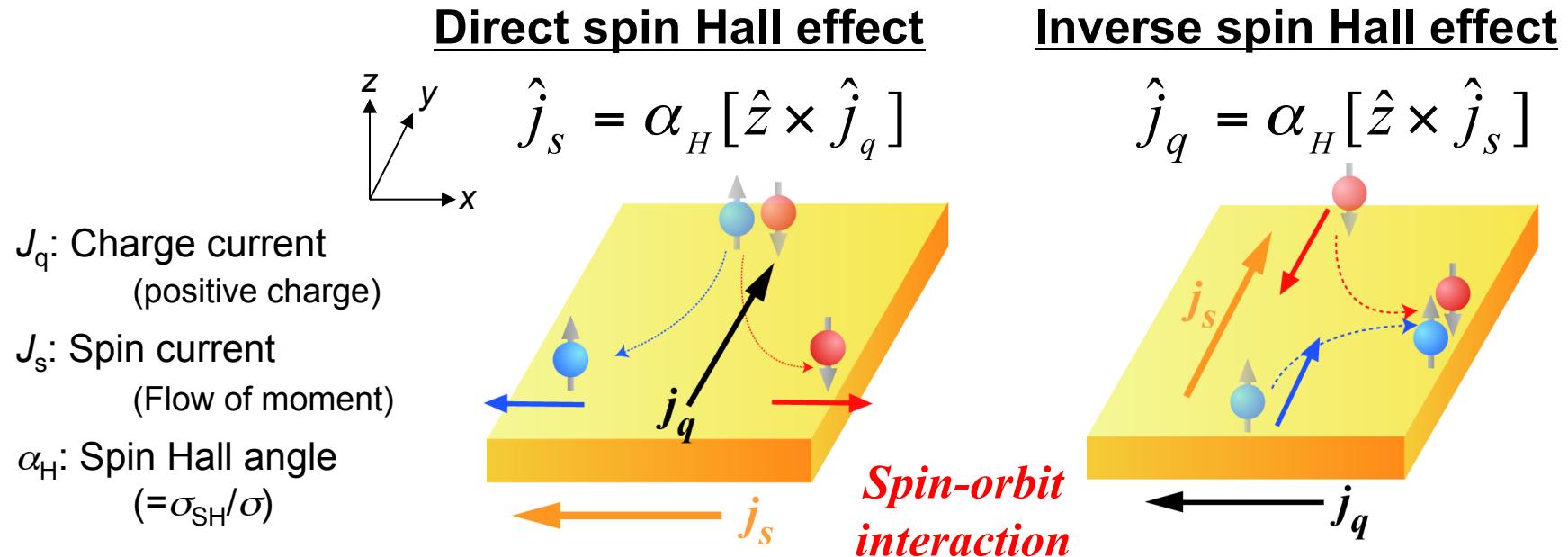
from ferromagnetic metal (FM)  
to nonmagnetic metal (NM)

*control of  
Spin relaxation*

# Research on *pure* spin current

## Generation of *pure* spin current

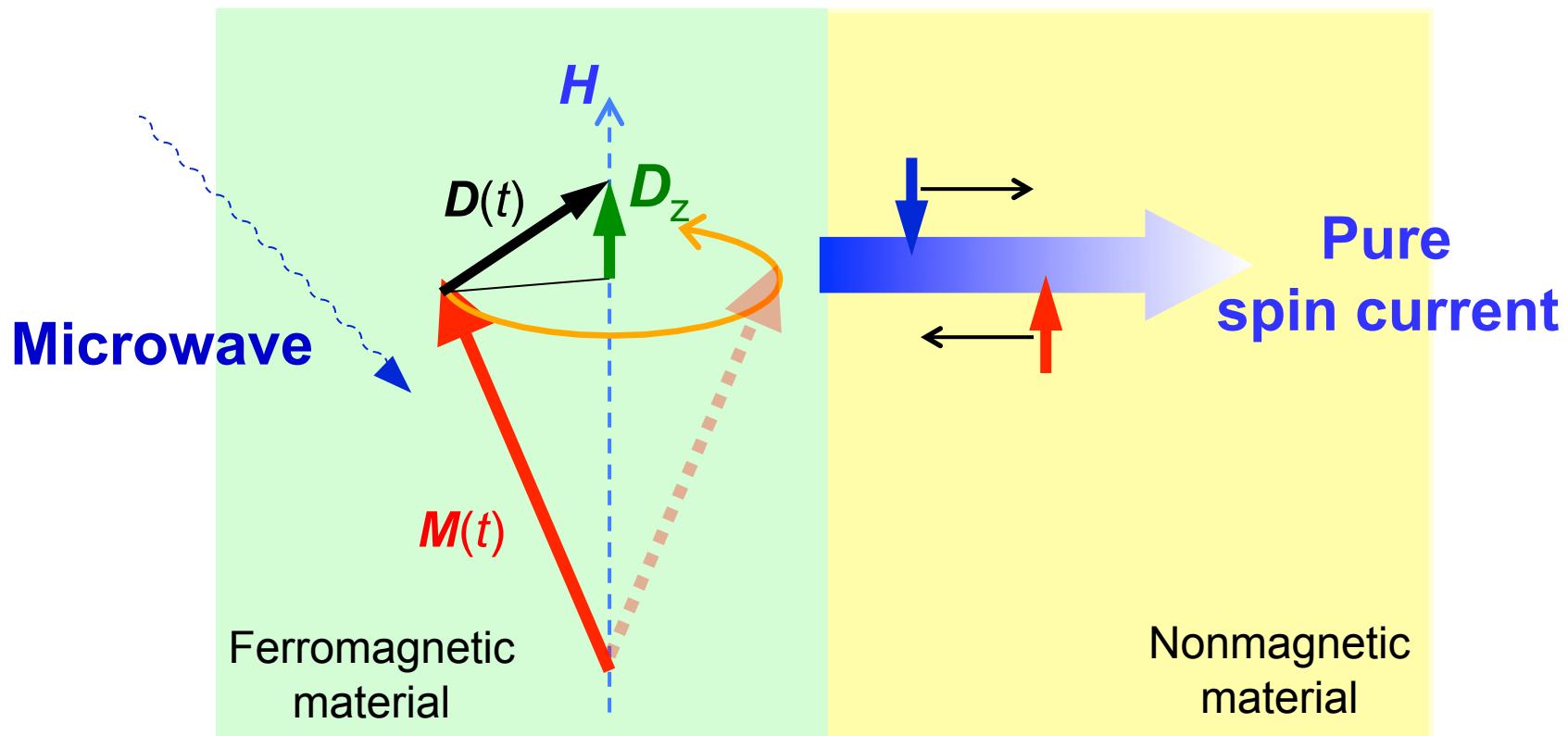
- Non-local spin injection (electric current → spin current)
- Spin Hall effect (electric current → spin current)



# Research on *pure* spin current

## Generation of *pure* spin current

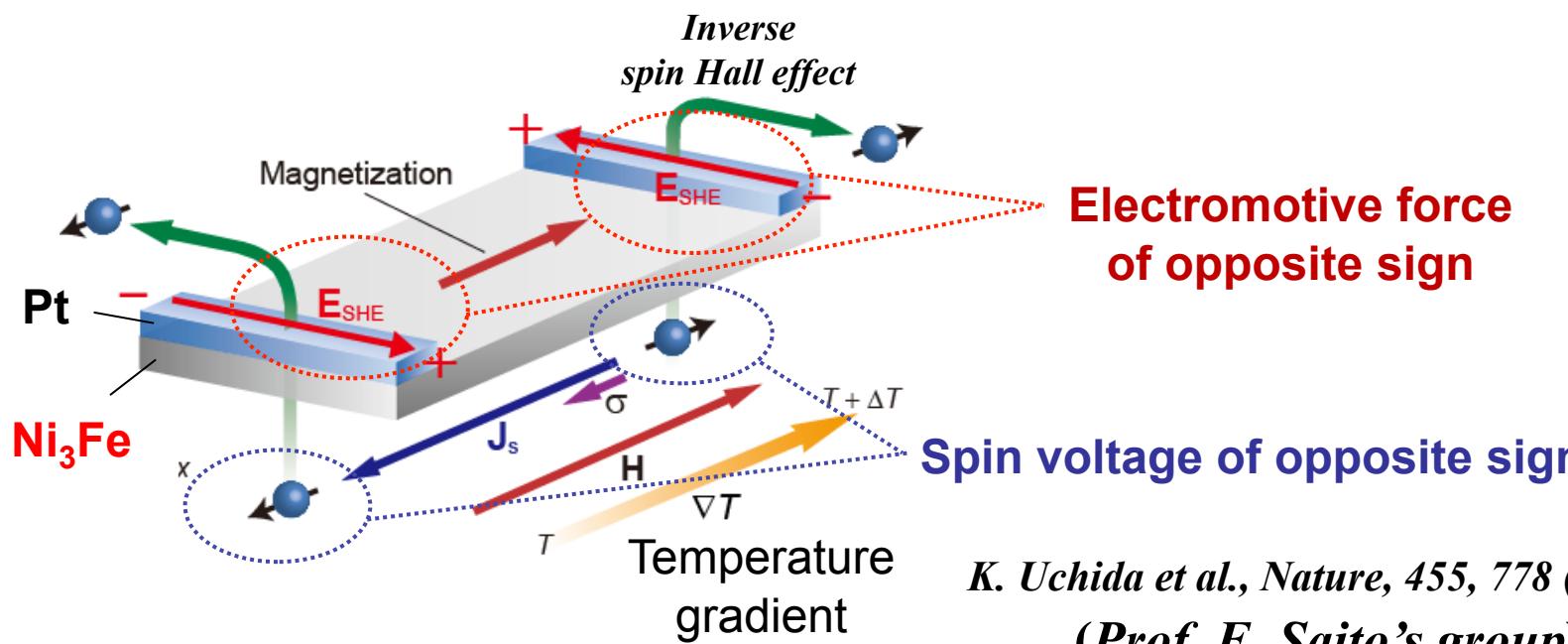
- Non-local spin injection (electric current → spin current)
- Spin Hall effect (electric current → spin current)
- Spin pumping (electromagnetic wave → spin current)



# Research on *pure* spin current

## Generation of *pure* spin current

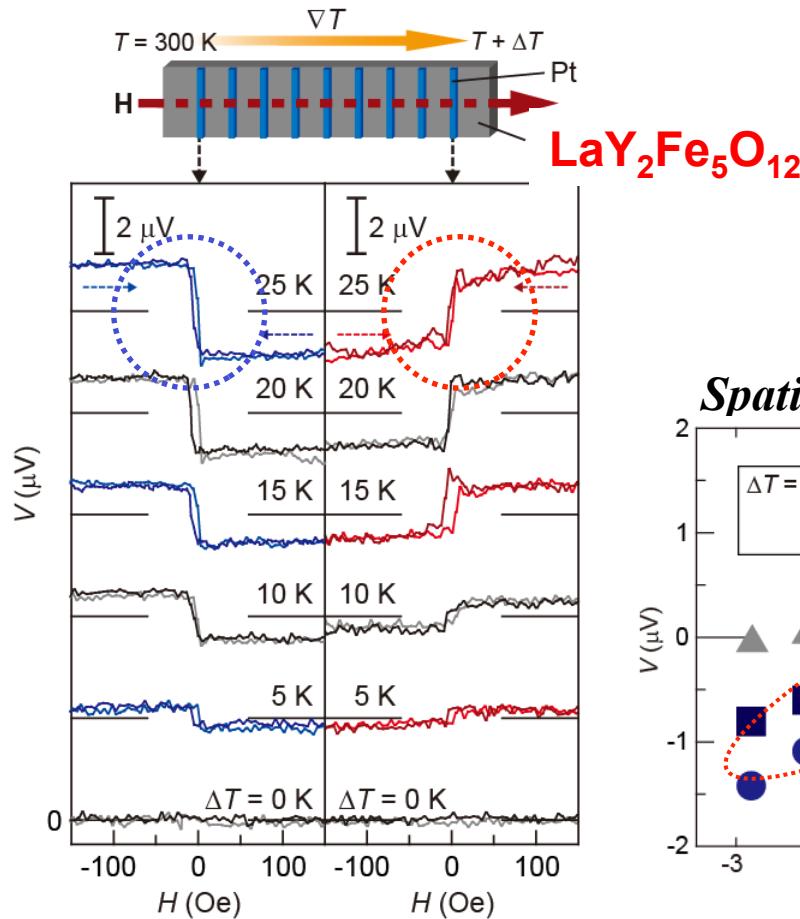
- Non-local spin injection (electric current → spin current)
- Spin Hall effect (electric current → spin current)
- Spin pumping (electromagnetic wave → spin current)
- Spin Seebeck effect (heat current → spin current)



K. Uchida et al., Nature, 455, 778 (2008).  
(Prof. E. Saito's group)

# Spin Seebeck insulator by E. Saitoh's group

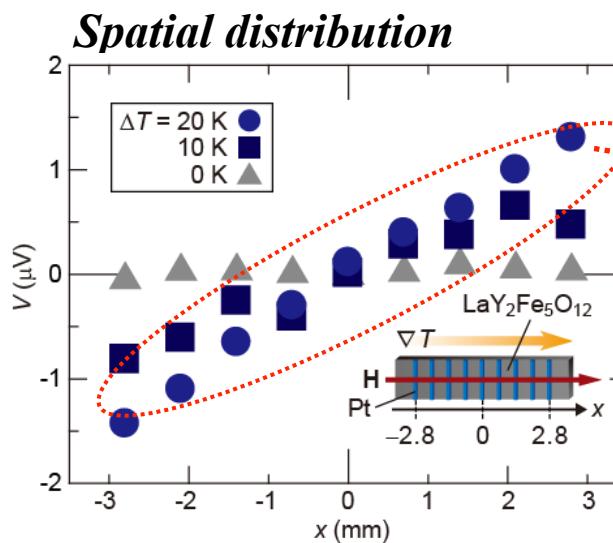
K. Uchida et al., *Nature Mater.*, 9, 894 (2010).



Temperature difference dependence  
of spin voltage

Spin Seebeck effect appears  
even in a magnetic insulator

Magnon spin current



Similar behavior to  $\text{Ni}_3\text{Fe}$

Opposite sign of spin  
voltage at the edges

+  
distribution in mm scale

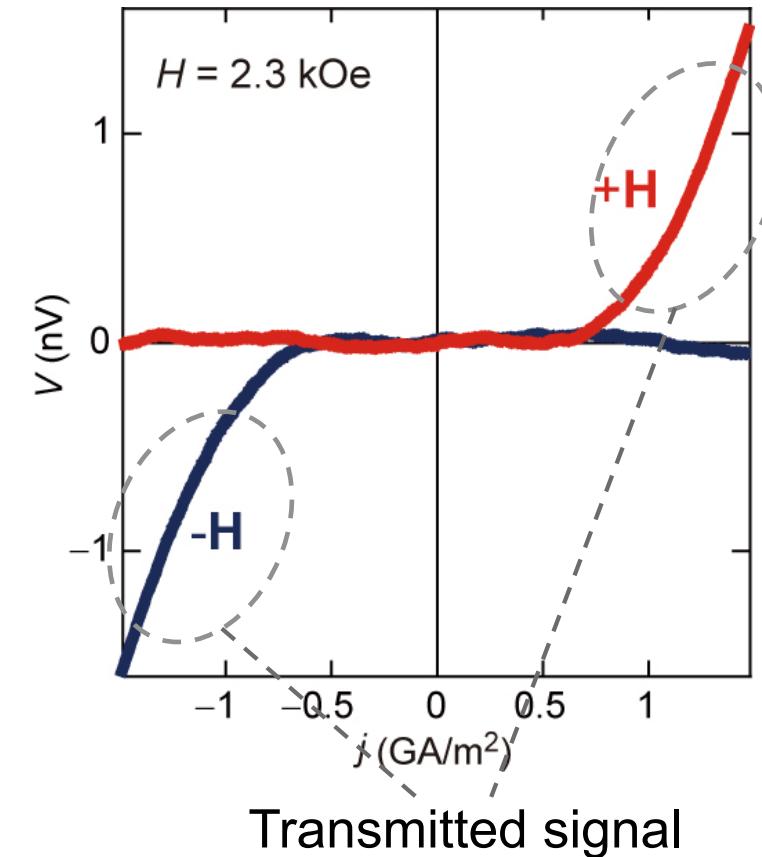
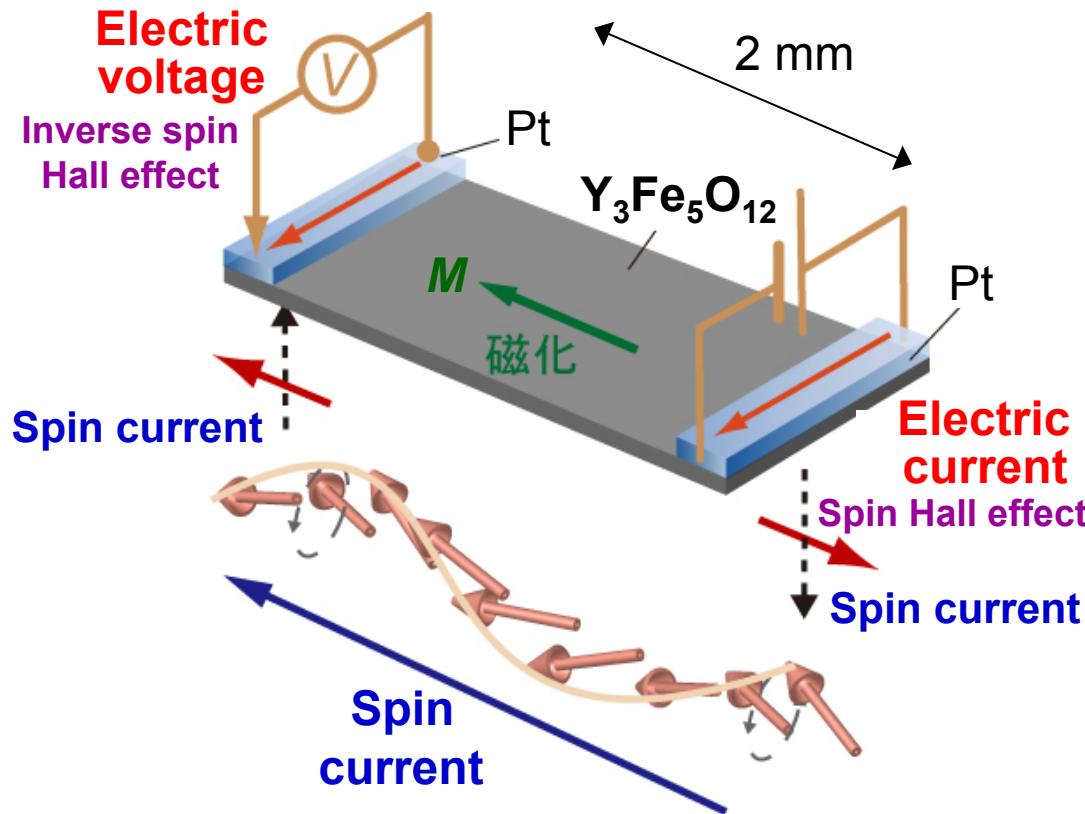
Development of Spin Caloritronics  
Application to Energy Harvesting

# Transmission of pure spin current

by Saitoh's group in collaboration with Maekawa and Takanashi groups

*Y. Kajiwara et al., Nature, 464 (2010) 262.*

## Transmission of pure spin current; metal $\rightarrow$ insulator $\rightarrow$ metal

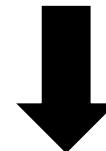


**Transmission of electric signal through spin current  
in a magnetic insulator**

# Keywords for spintronics

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*Spin polarization*  
*Spin injection*  
*Spin relaxation*



**Efficient generation and precise control  
of spin current**

# Topics of materials for spintronics

---

- **Spin polarization**

Highly spin polarized (half metallic)

Heusler alloys ( $\text{Co}_2\text{MnSi}$ ,  $\text{Co}_2\text{Fe(Al,Si)}$ , etc.)

Perpendicularly spin polarized

High magnetic anisotropy:  $\text{L}1_0$  ordered alloys (FePt, etc.)

- **Spin injection**

Magnetic metal / semiconductor junction

$\text{CoFe/Si}$ ,  $\text{Fe/GaAs}$ , etc.

Metal / magnetic insulator junction

$\text{Pt} / \text{Y}_3\text{Fe}_5\text{O}_{12}$ , etc.

- **Spin relaxation**

Nanoparticles → *size effect*

Molecular / carbon-based materials → *weak LS coupling*

Magnetic insulator → *low magnetization damping*

# Topics of materials for spintronics

---

## ▪ Spin polarization

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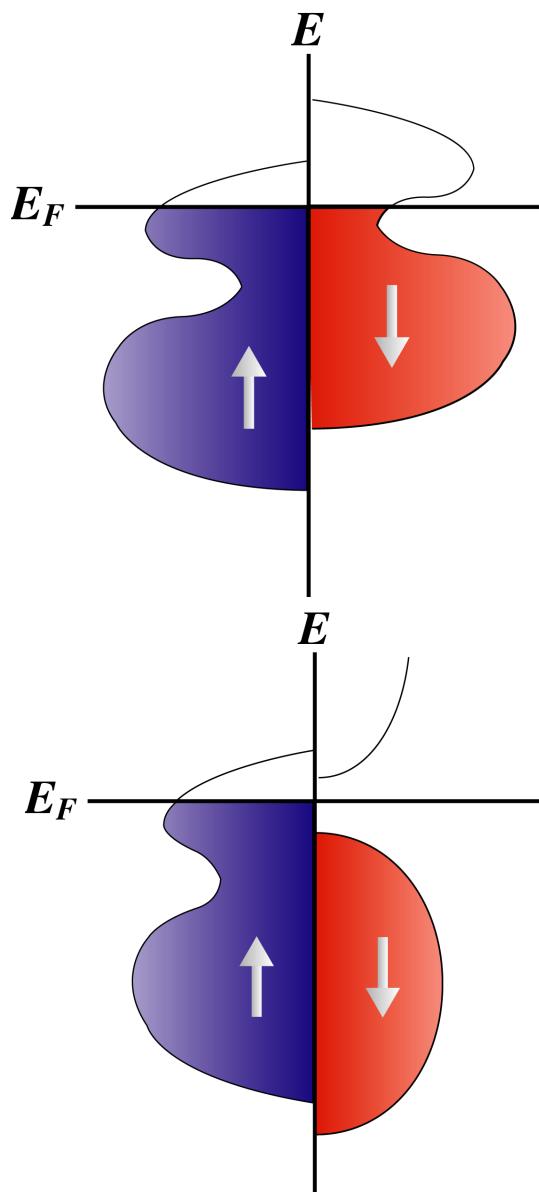
Nanoparticles → *size effect*

Molecular / carbon-based materials → *weak LS coupling*

Magnetic insulator → *low magnetization damping*

# **Highly spin-polarized materials: half-metallic Heusler alloys**

# Half-metals



Spin polarization of conduction electrons

$$P = \frac{D_{\uparrow}(E_F) - D_{\downarrow}(E_F)}{D_{\uparrow}(E_F) + D_{\downarrow}(E_F)}$$

- Conventional 3d ferromagnetic metal and alloys: Fe, Co, Ni, NiFe, ...

$P = 0.4 \sim 0.5$  typically

- **Half metals**

**$P = 1$**

Heusler alloys:

NiMnSb, Co<sub>2</sub>MnSi, Co<sub>2</sub>MnAl, etc.

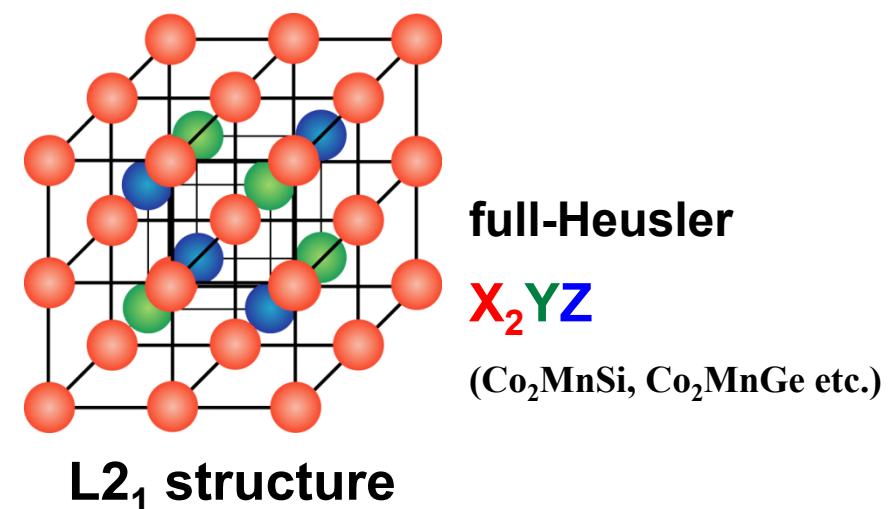
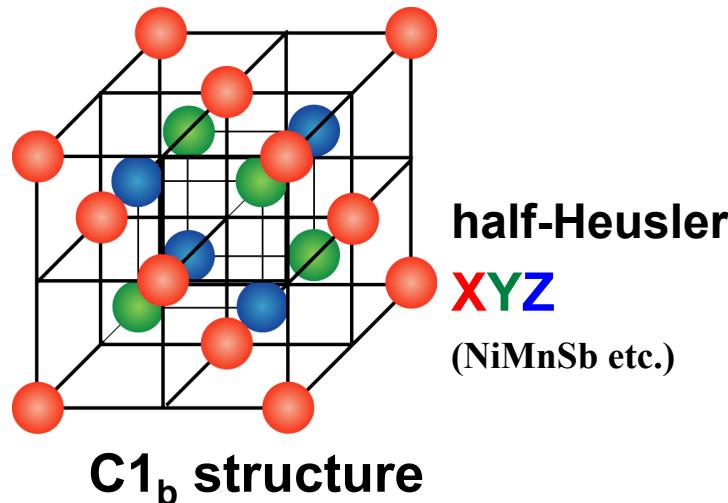
Transition metal oxides:

CrO<sub>2</sub>, Fe<sub>3</sub>O<sub>4</sub>, LSMO, etc.

→ **Efficient spin injection**

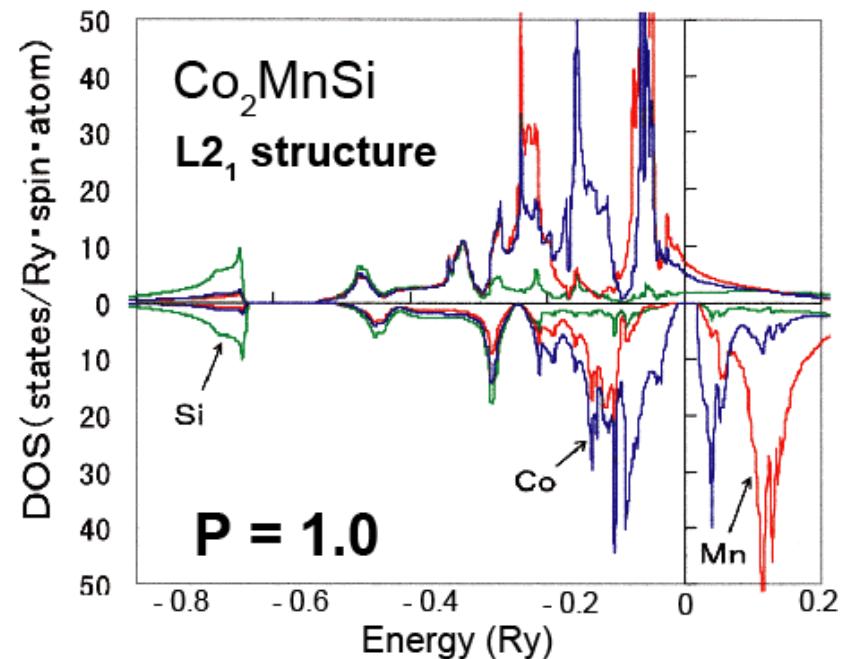
**High performance of spintronics devices**

# Half metallic Heusler alloys

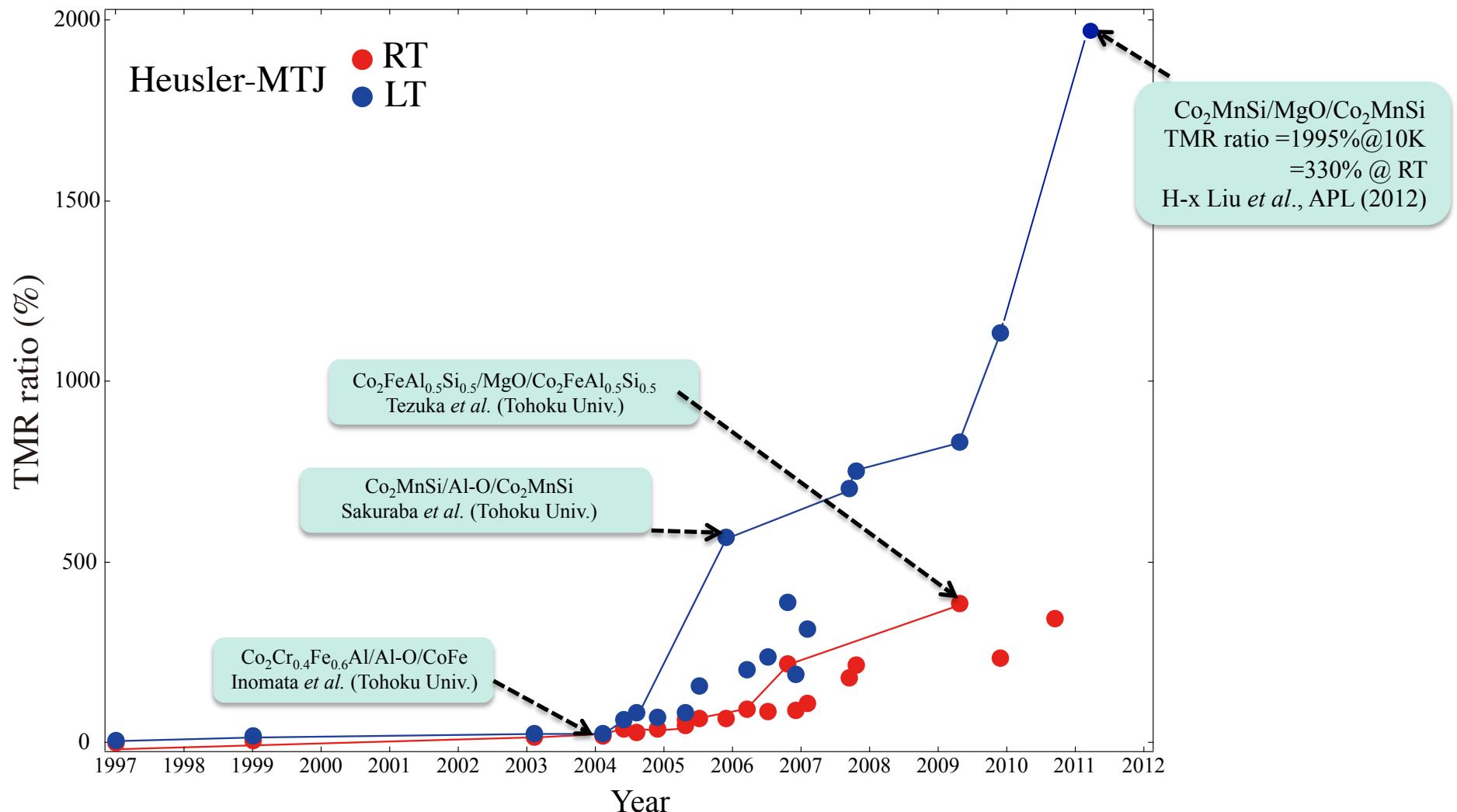


## Co<sub>2</sub>MnSi (CMS)

- Half-metallic energy gap : 400 – 600 meV
- High  $T_c$  ( $\sim 985\text{K}$ )
- Highly ordered L<sub>2</sub>1-structure is easily obtained.



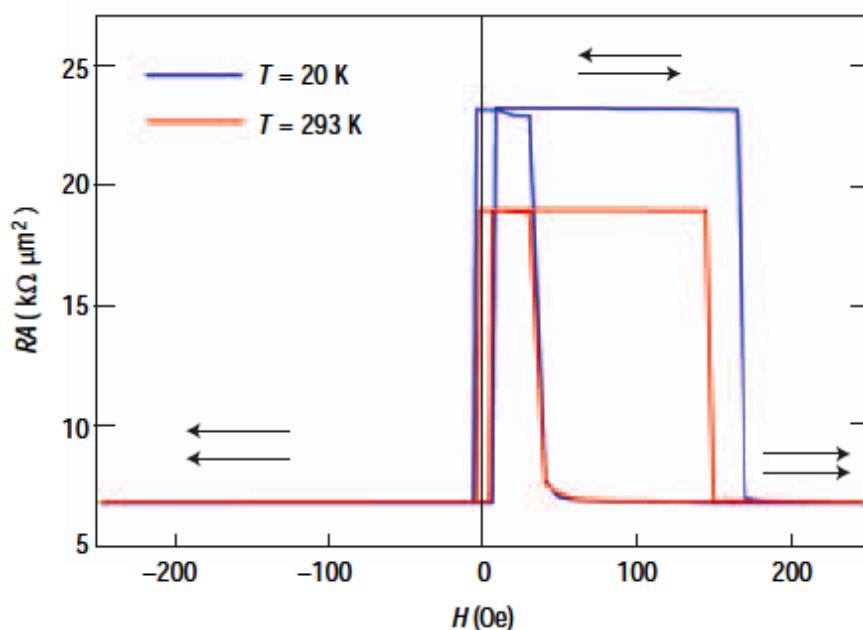
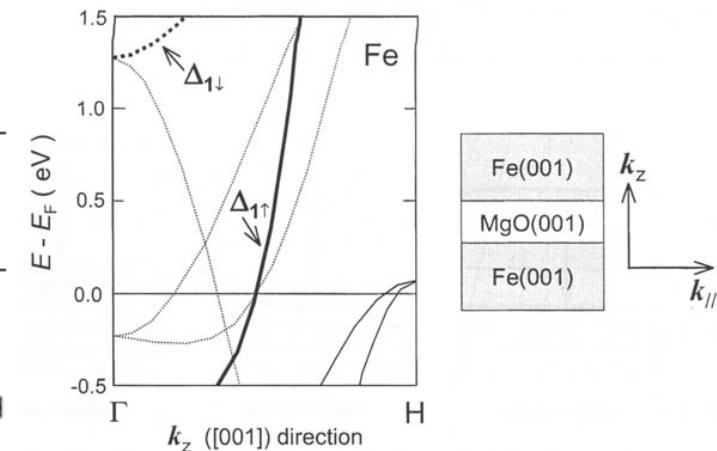
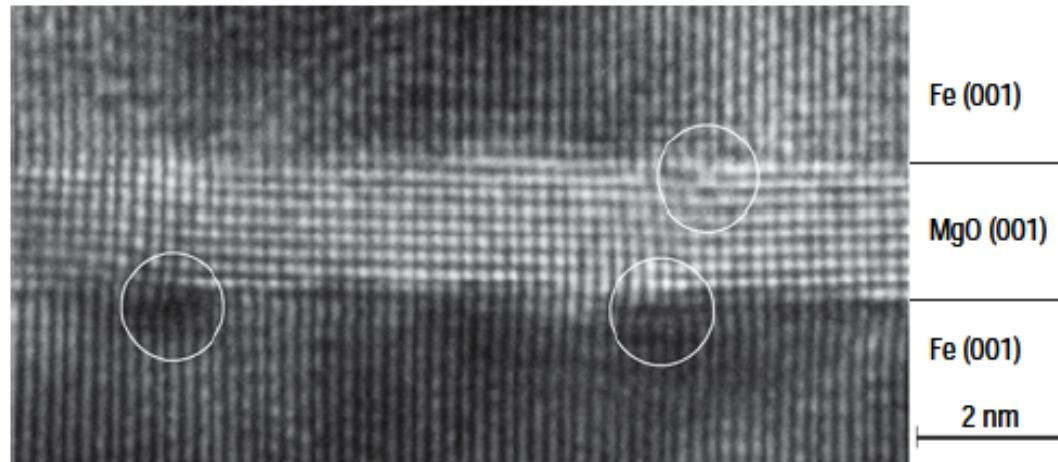
# MTJs with half-metallic Heusler alloys



Heusler-based MTJ : Large temperature dependence of MR ratio is still a serious problem especially in CMS.

# Giant TMR in MgO-MTJ

Fe (001) / MgO (001) / Fe (001) single crystal

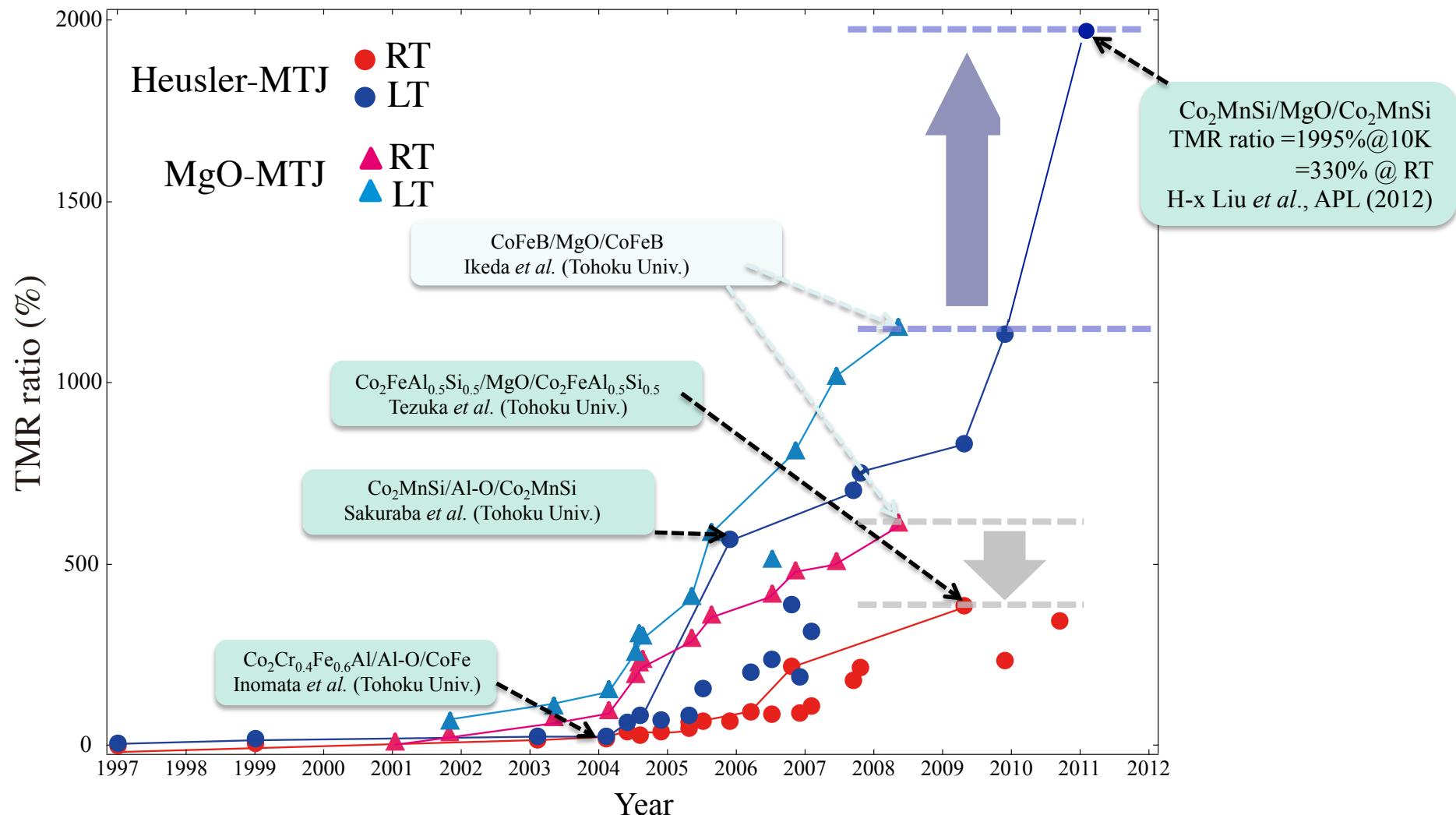


Band structure of Fe  
 $\Delta_1$  band: *half metallic* nature

$$\text{MR} = 180\% \text{ (RT)} \\ 247\% \text{ (4.2K)}$$

S. Yuasa *et al.*,  
Jpn. J. Appl. Phys., **43** (2004) L588.  
Nat. Mater., **3** (2004) 868.

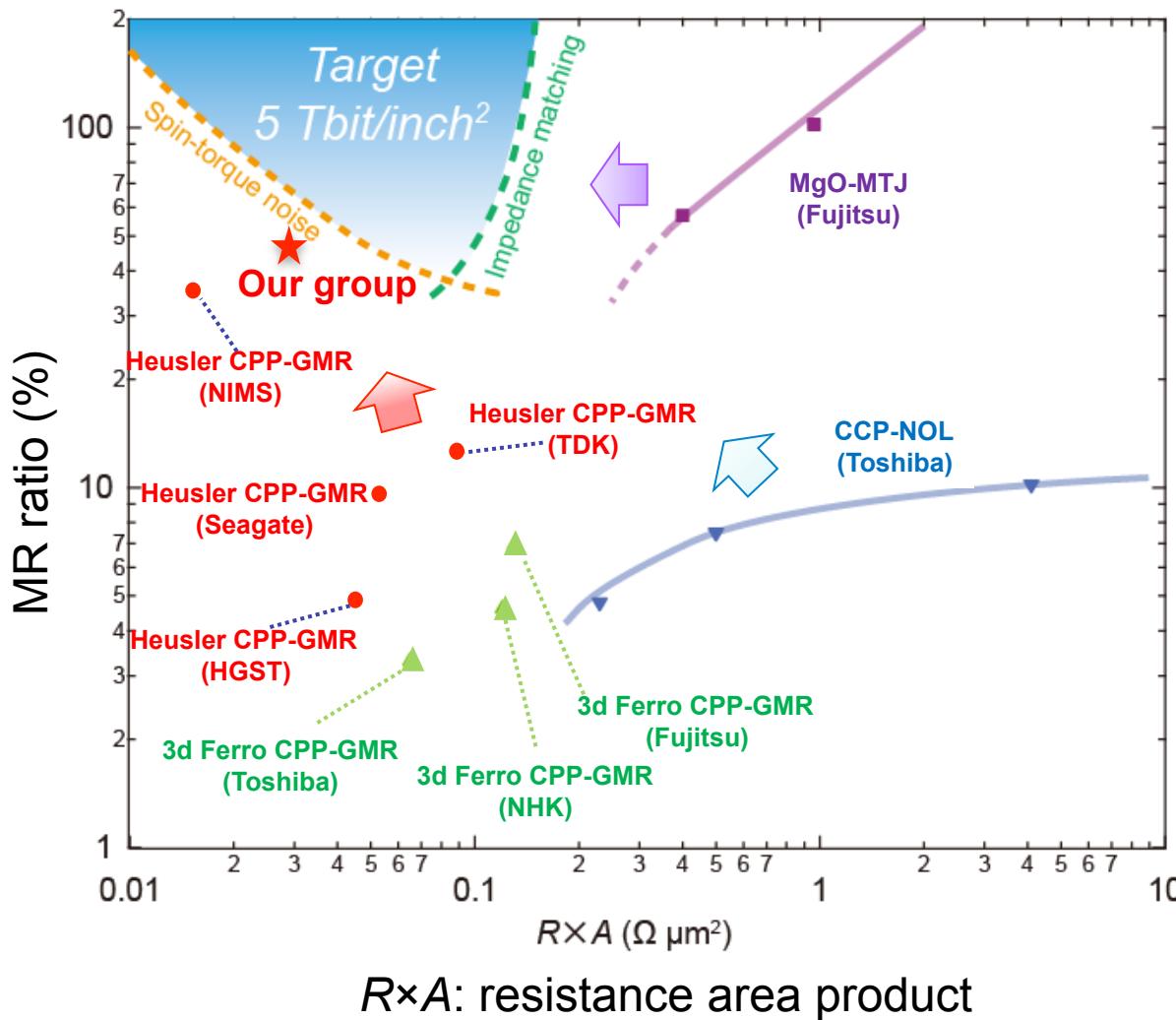
# MTJs with half-metallic Heusler alloys



Heusler-based MTJ : Large temperature dependence of MR ratio is still a serious problem especially in CMS.

# High MR and low resistance

Reported MR ratio in small RA region



Essential decrease in TMR with reducing resistance

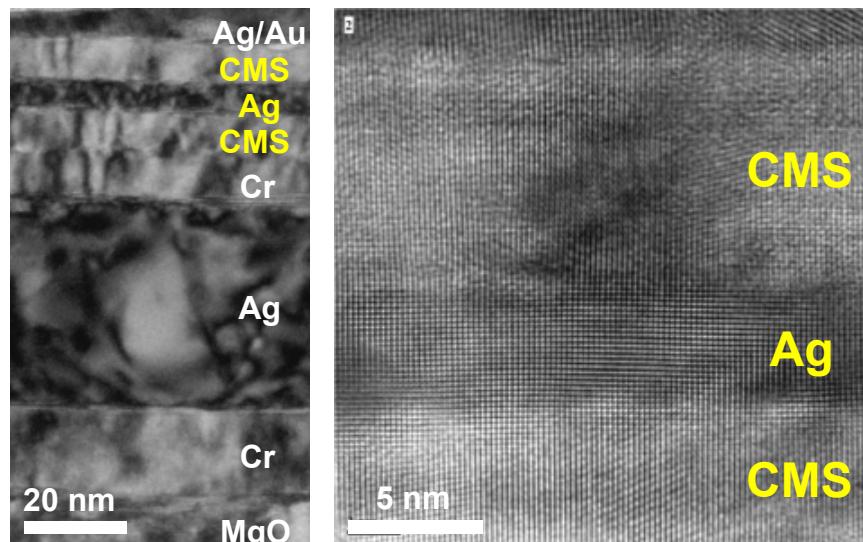
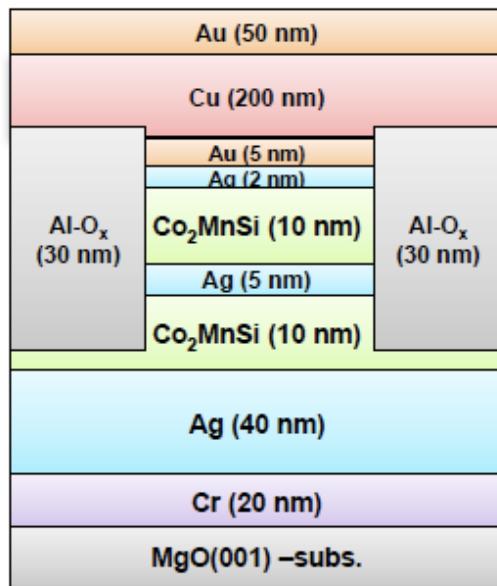


Half metals (P=100 %):  
Heusler alloys are still promising!

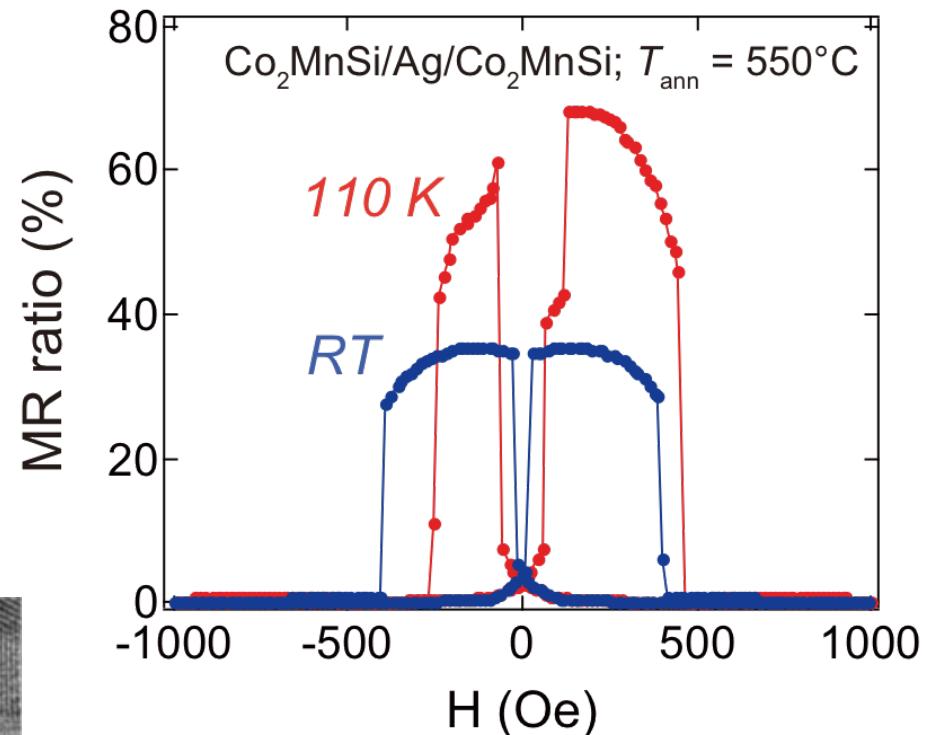
TMR

CPP-GMR

# CMS/Ag/CMS fully epitaxial CPP-GMR device



Fully epitaxial growth in CMS/Ag/CMS

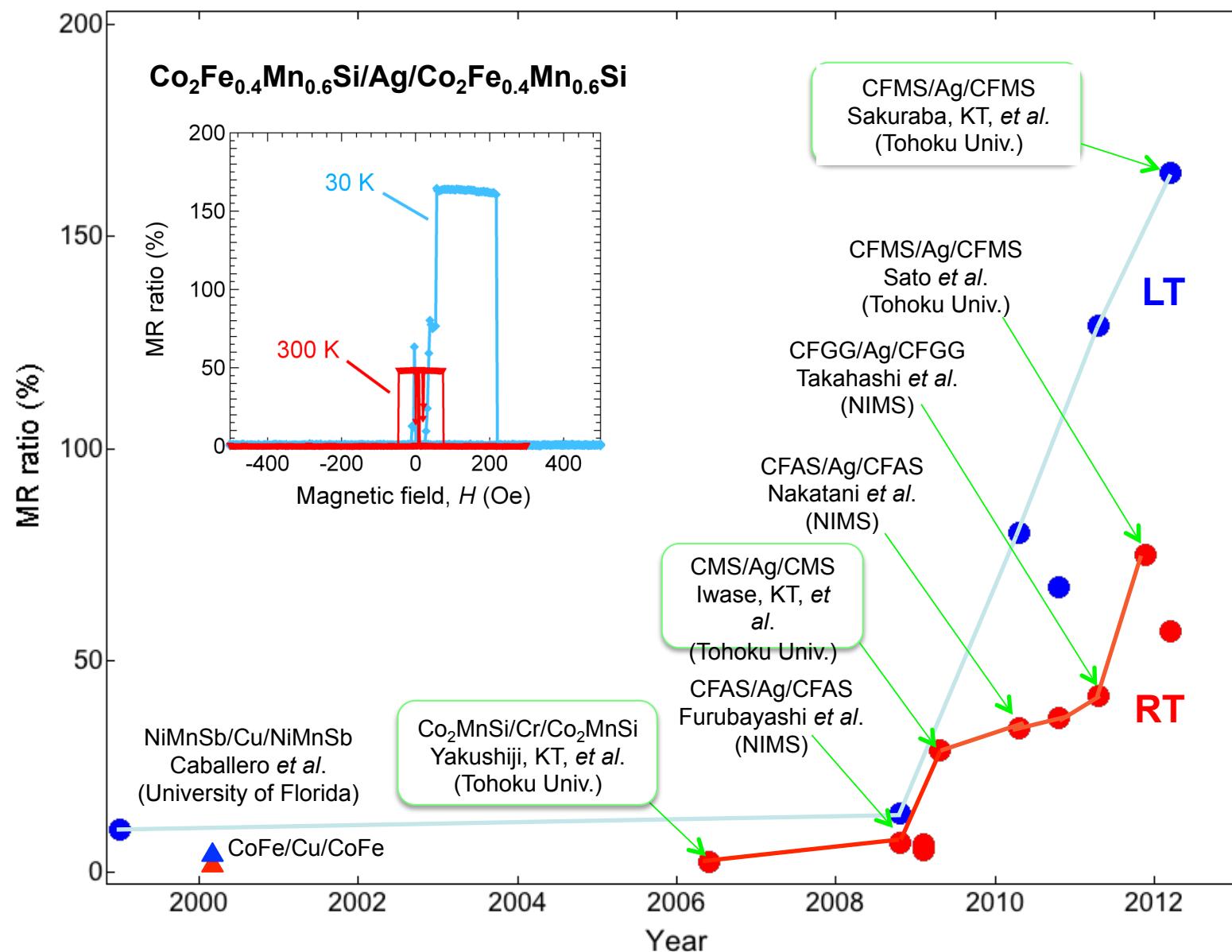


Breakthrough of CPP-GMR

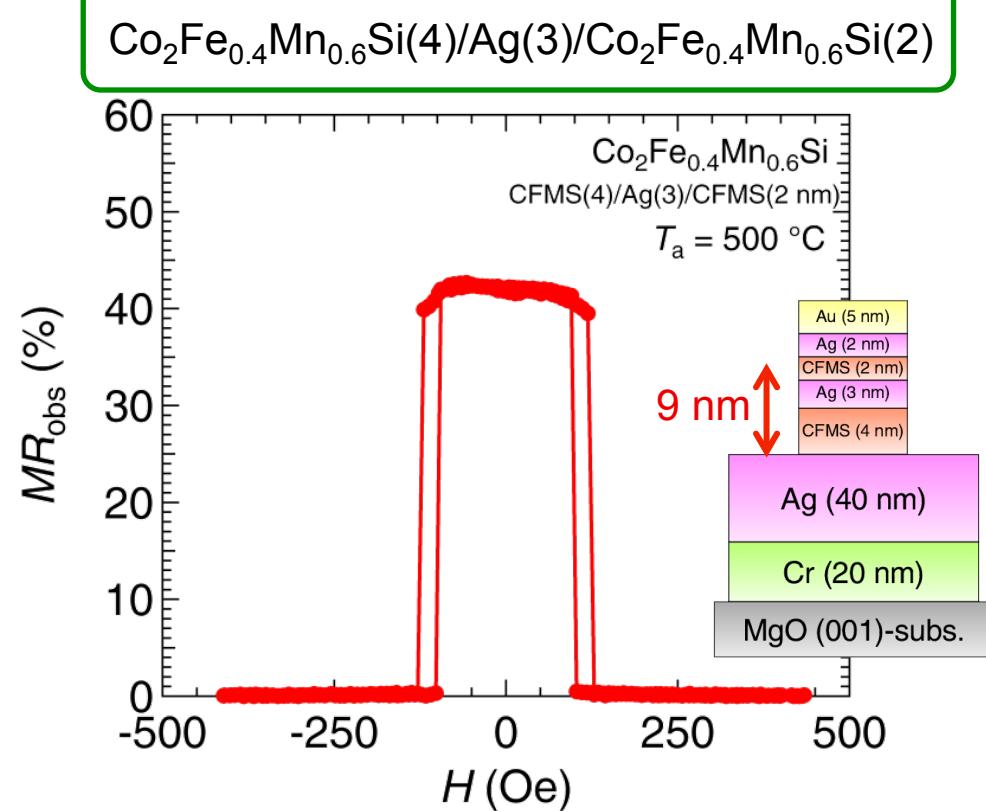
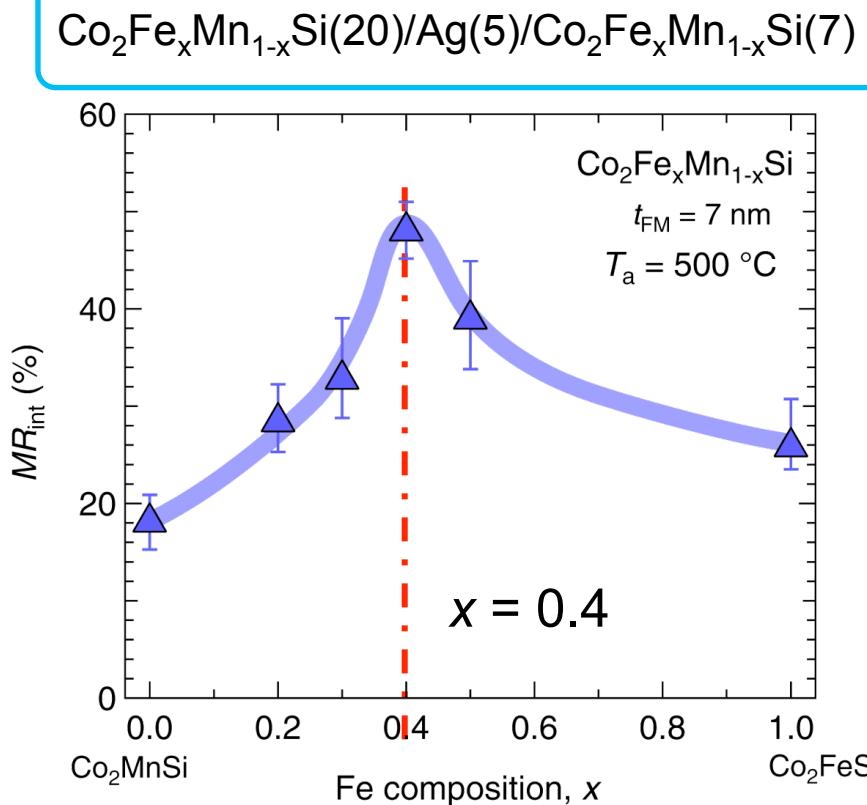
A high MR ratio (36.4%@RT) was observed.

T. Iwase, KT *et al.*, Appl. Phys. Exp., 2 (2009) 063003.  
Y. Sakuraba, KT *et al.*, Phys. Rev. B82 (2010) 094444.

# Development of CPP-GMR for Heusler alloys



# CPP-GMR in CFMS/Ag/CFMS



Best composition ratio :  $\text{Co}_2\text{Fe}_{0.4}\text{Mn}_{0.6}\text{Si}$

Average MR ratio	$RA$	$\Delta RA$
48 %	$24.3 \text{ m}\Omega \cdot \mu\text{m}^2$	$11.8 \text{ m}\Omega \cdot \mu\text{m}^2$

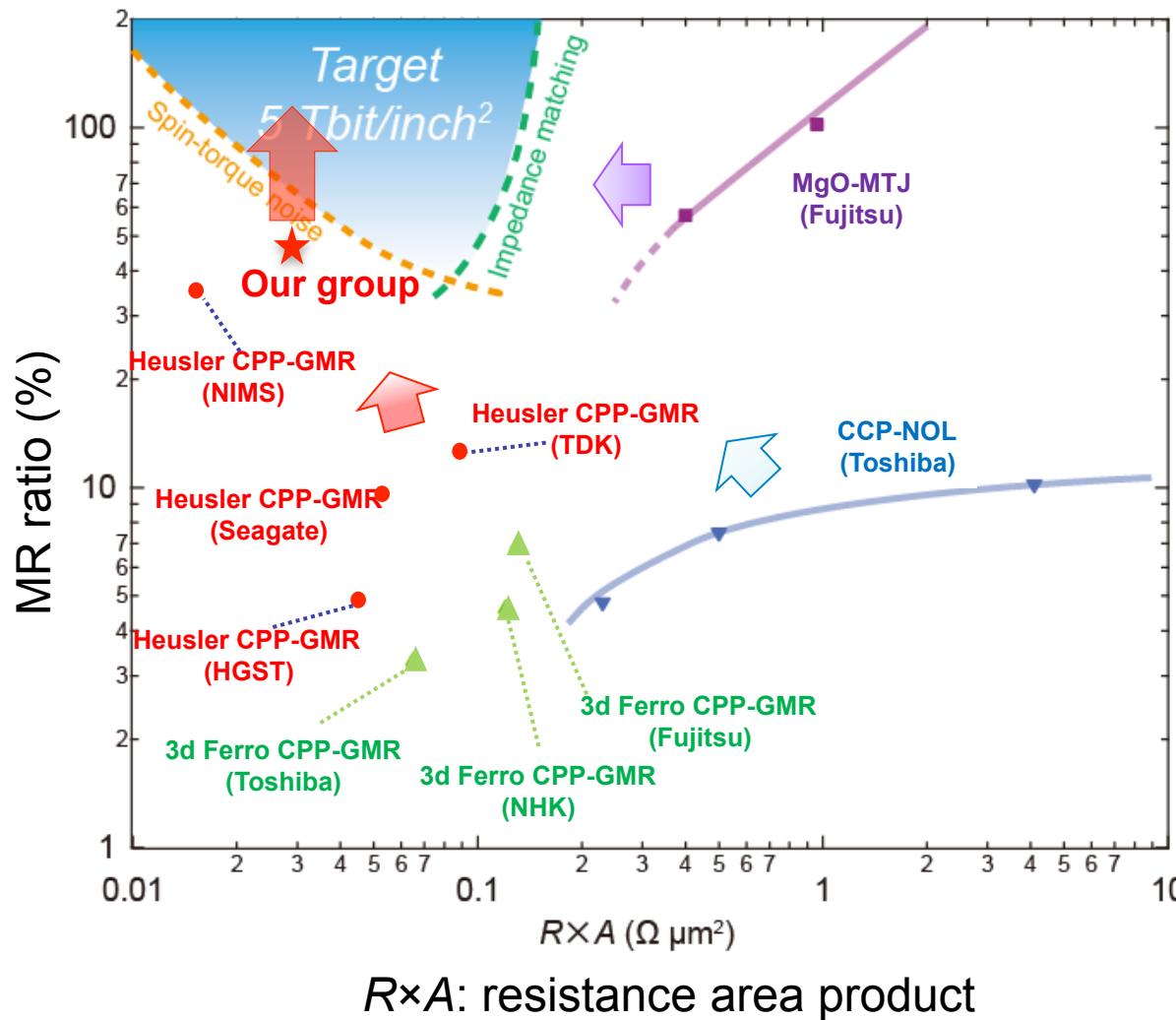
$MR_{int}$	$RA$	$\Delta RA$
58%	$21.7 \text{ m}\Omega \cdot \mu\text{m}^2$	$12.5 \text{ m}\Omega \cdot \mu\text{m}^2$

Y.Sakuraba, KT, et al. Appl. Phys. Lett., 101 (2012) 252408.

Large MR ratio even in very thin trilayer structure !

# High MR and low resistance

Reported MR ratio in small RA region



Essential decrease in TMR with reducing resistance

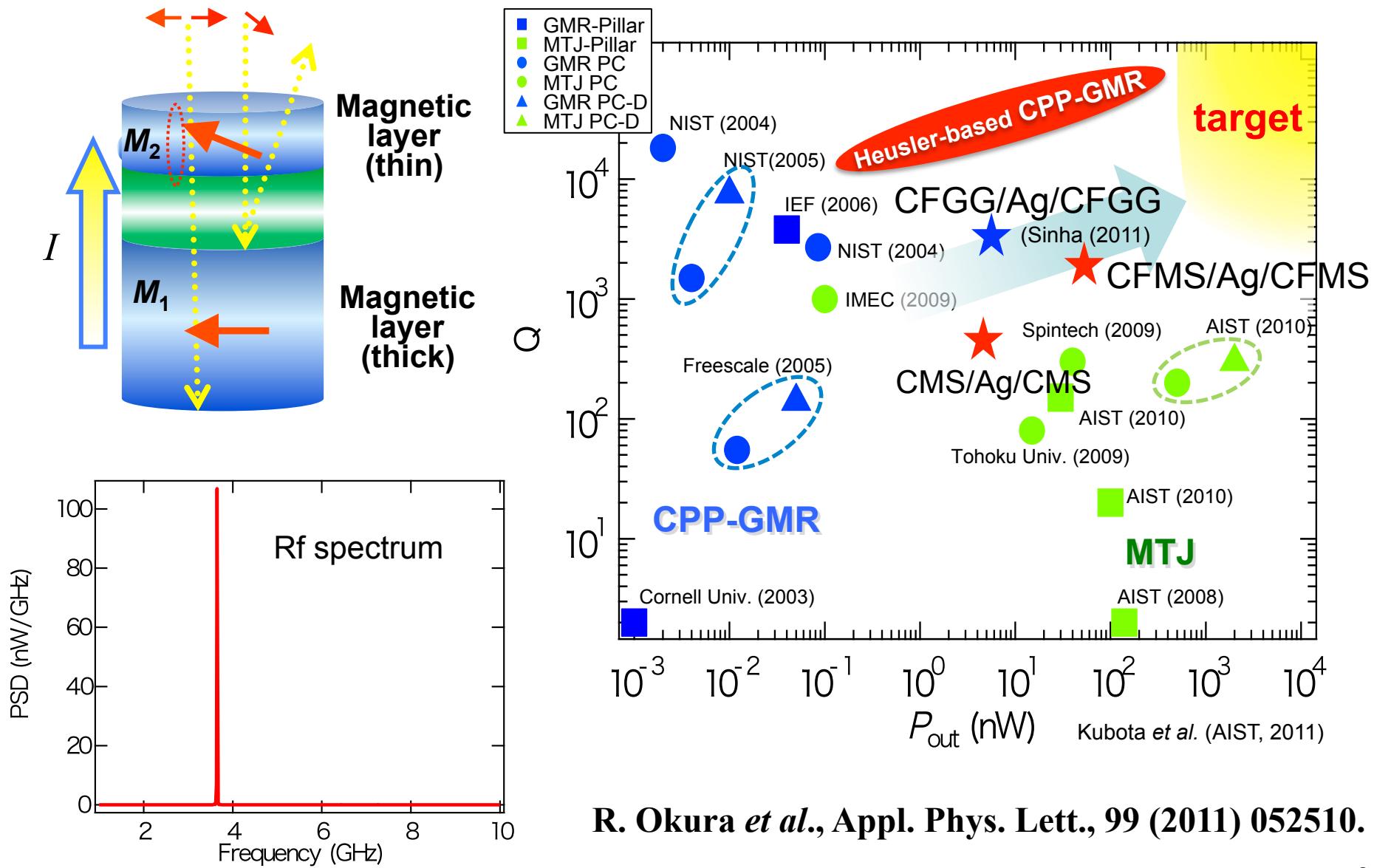


Half metal ( $P=100\%$ ):  
Heusler alloys are still promising!

TMR

CPP-GMR

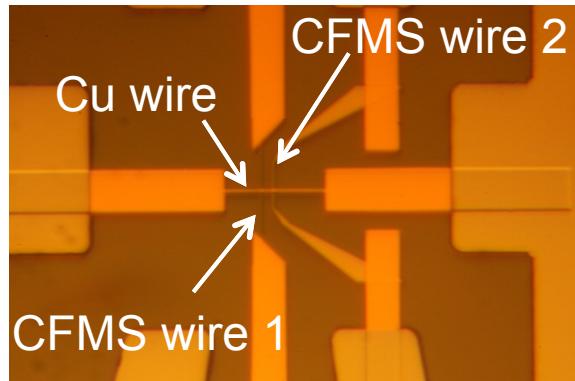
# Rf oscillation in Heusler alloys by spin transfer torque



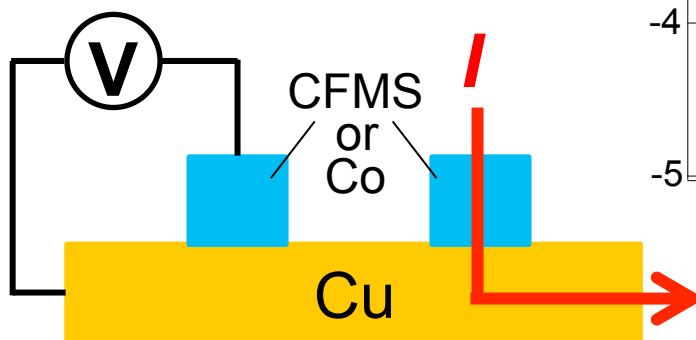
R. Okura *et al.*, Appl. Phys. Lett., 99 (2011) 052510.

# Non-local spin injection in lateral spin valves

$\text{Co}_2\text{Fe}_{0.4}\text{Mn}_{0.6}\text{Si}$ (CFMS)/Cu

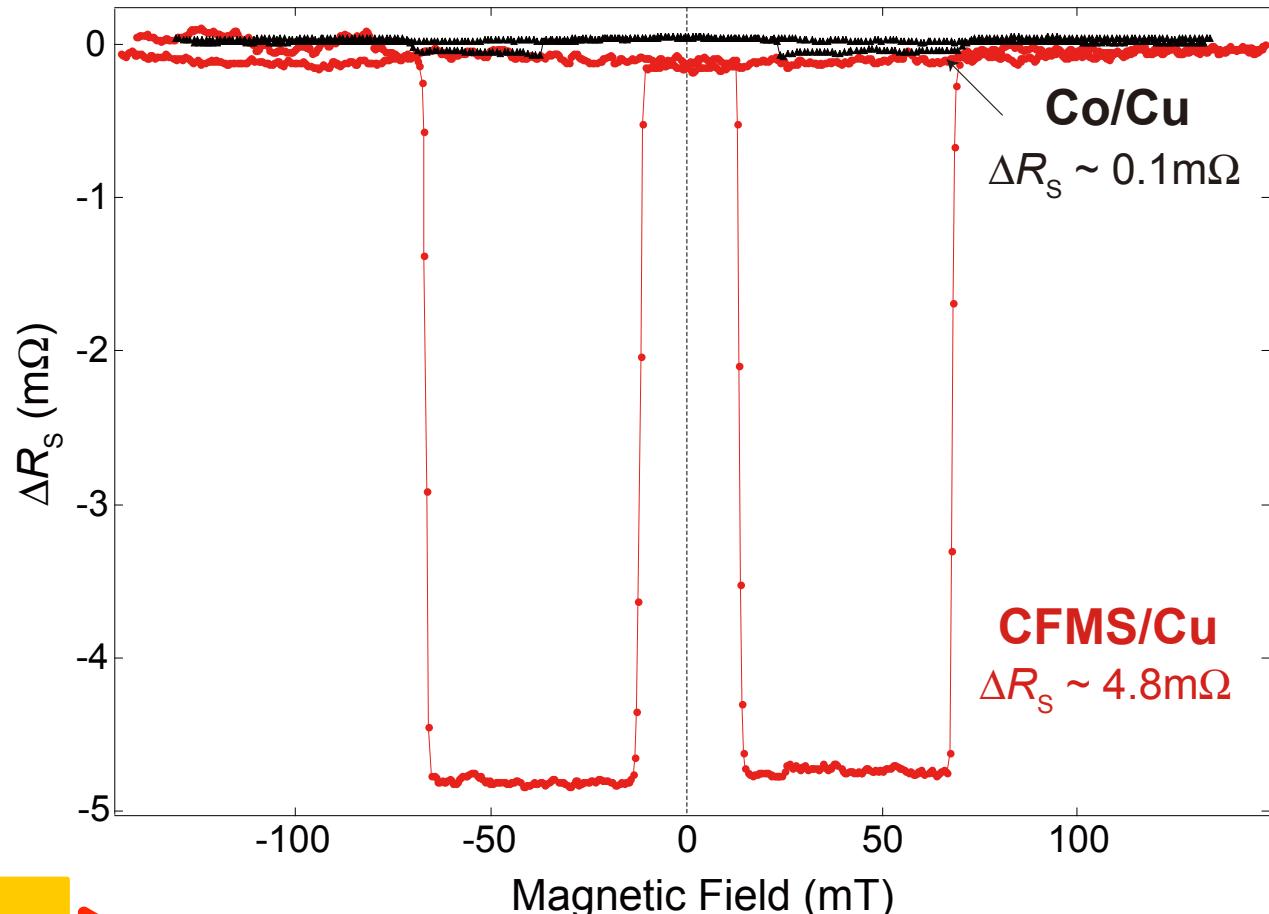


Y. Sakuraba *et al.*,  
unpublished.



Non-local spin injection

NLSV signal@RT, gap = 350 nm



Observation of large spin accumulation signal  
Spin injection with high efficiency

**Perpendicularly spin-polarized materials:  
 $L1_0$ -ordered alloys  
with high magnetic anisotropy**

# Perpendicular magnetization and spintronics

High magnetic anisotropy → Thermal stability of magnetization

Negative shape anisotropy → Easy magnetization switching

No restriction on aspect ratio

High Integration

## Examples of perpendicularly magnetized films

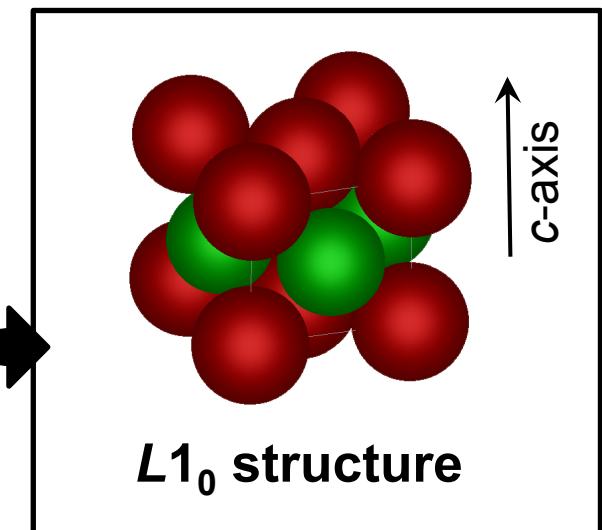
Co-based granular films such as CoCrPt-SiO<sub>2</sub>

RE-TM amorphous alloy films such as TbFeCo

Metallic multilayers or ultrathin films

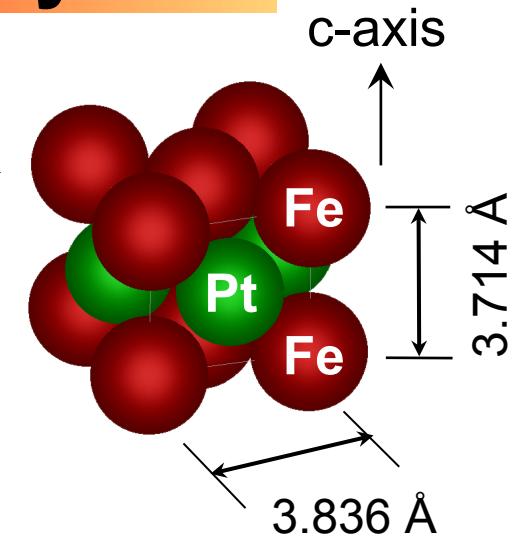
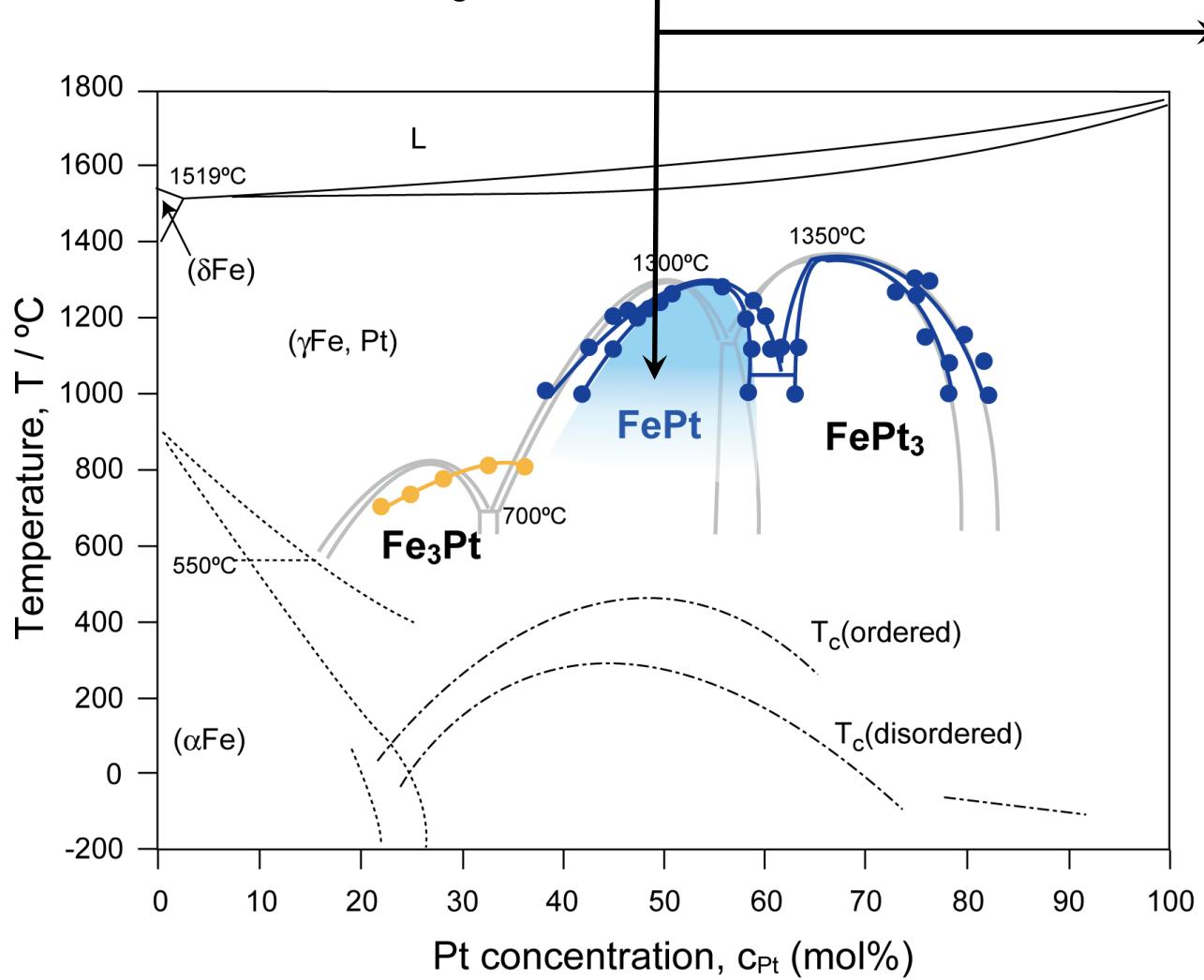
such as Ni/Co, Co/Pd, CoFeB/MgO, etc.

$L1_0$  ordered alloy films such as FePt, FePd, CoPt, etc.



# $L1_0$ ordered FePt alloy

## $L1_0$ ordered phase



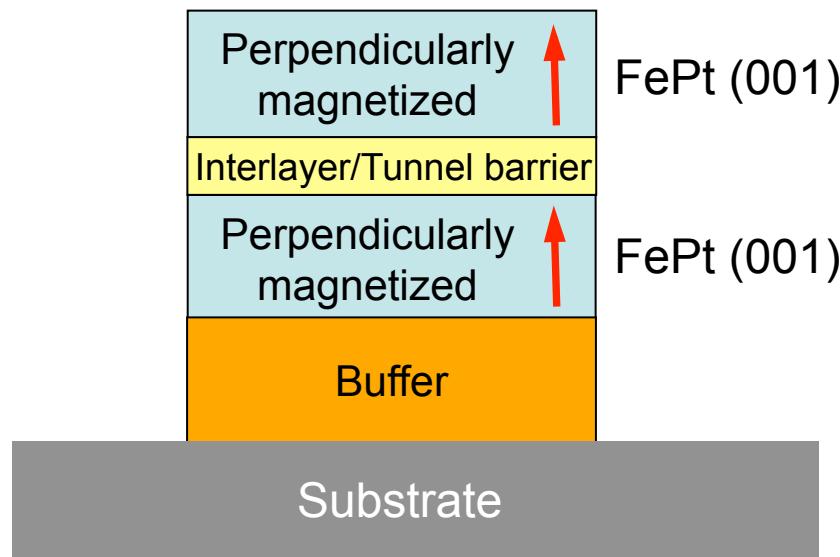
Large uniaxial magnetic anisotropy  
 $K_u = 7 \times 10^7$  erg/cm<sup>3</sup>



- Perpendicular magnetic recording media
- Patterned media
- Spintronics

Phase diagram of Fe-Pt system

# Spin-torque switching of magnetization for $L1_0$ -FePt

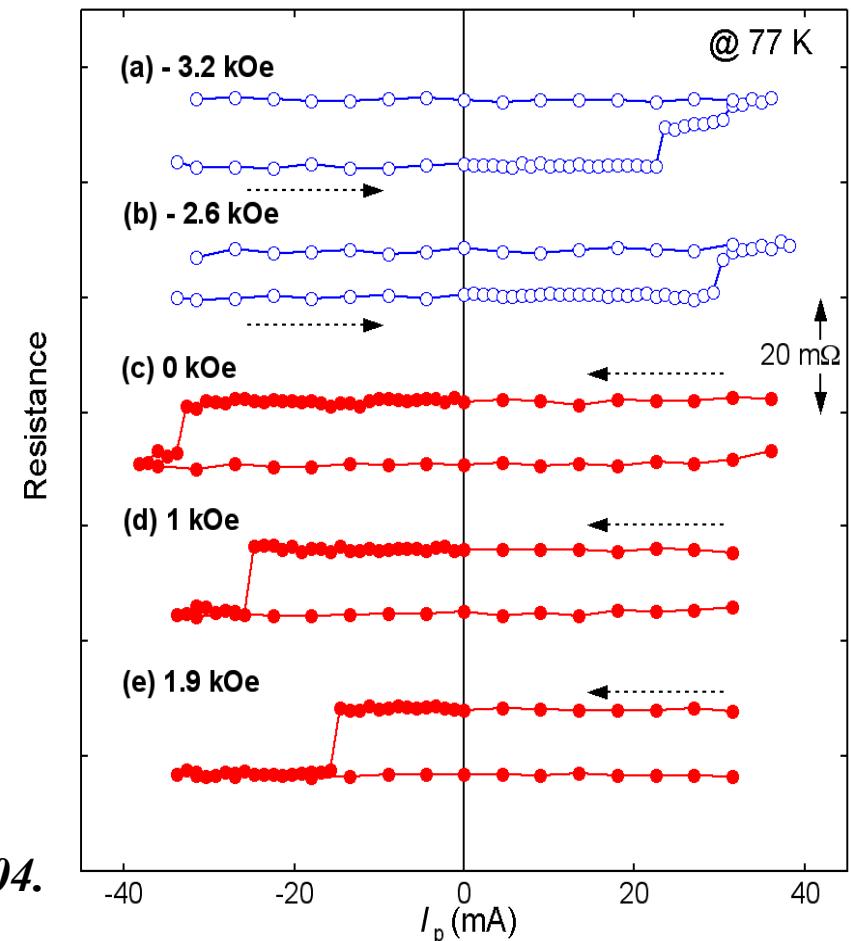


*Fully epitaxial*

**FePt / Au / FePt CPP-GMR pillars**

**Spin-torque switching of magnetization**

*T. Seki, KT, et al., Appl. Phys. Lett. 88 (2006) 172504.*



$[\text{Co}/\text{Pt}]_4 / [\text{Co}/\text{Ni}]_2 / \text{Cu} / [\text{Co}/\text{Ni}]_4$

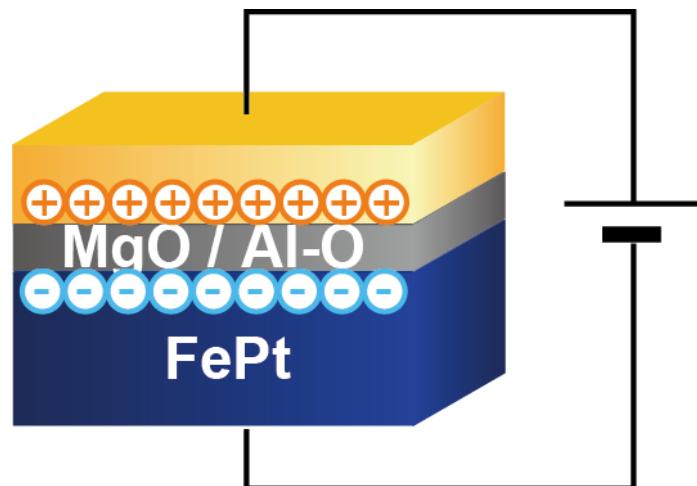
*S. Mangin et al., Nature Mater., 5 (2006) 210.*

$[\text{CoFe}/\text{Pt}]_5 / \text{Cu} / [\text{CoFe}/\text{Pt}]_7$

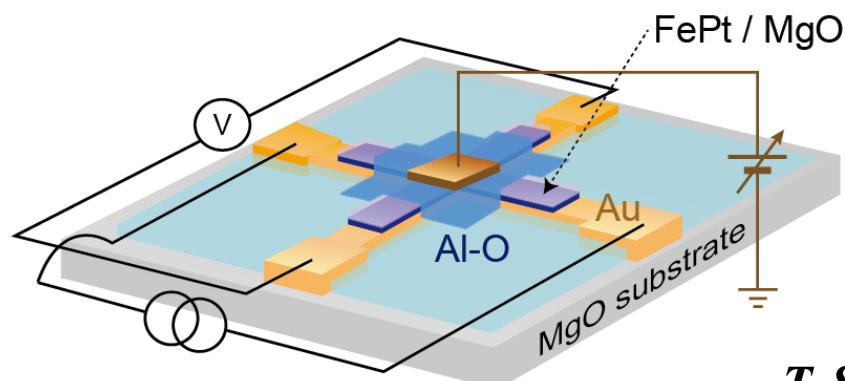
*H. Meng and J.-P. Wang, Appl. Phys. Lett., 88 (2006) 172506.*

# Coercivity control by electric field for $L1_0$ -FePt

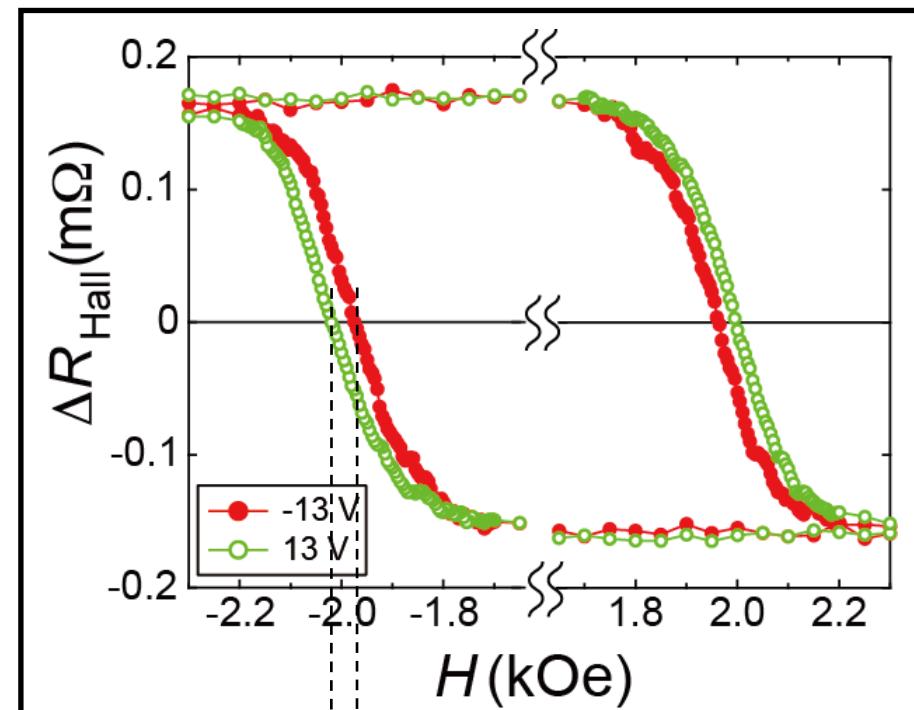
Perpendicularly magnetized  $L1_0$ -FePt



FePt / MgO / Al-O Hall device



Anomalous Hall resistance curve



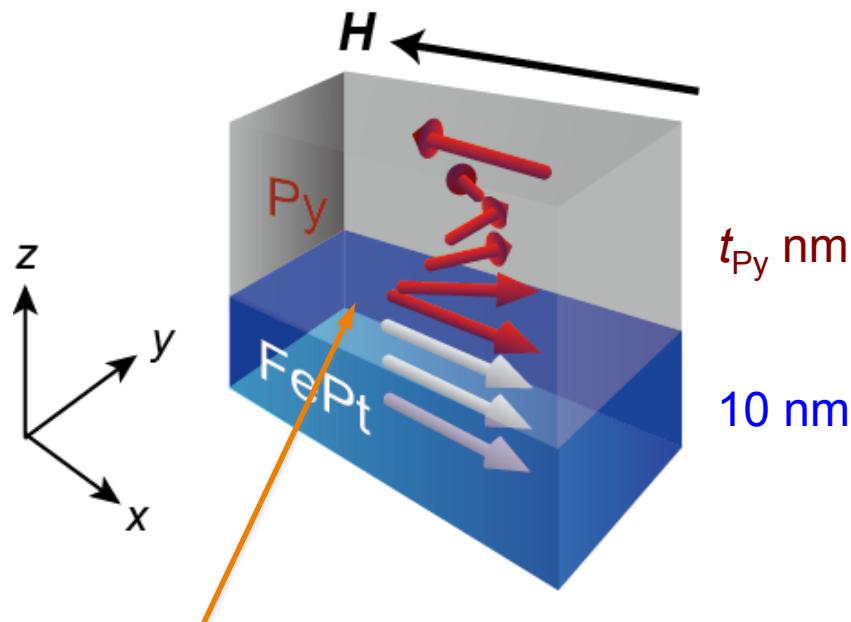
$H_c$  modulation  
by changing  $V_{\text{app}}$  (-13 ~ 13V)

T. Seki, KT, et al., Appl. Phys. Lett., 98 (2011) 212505.

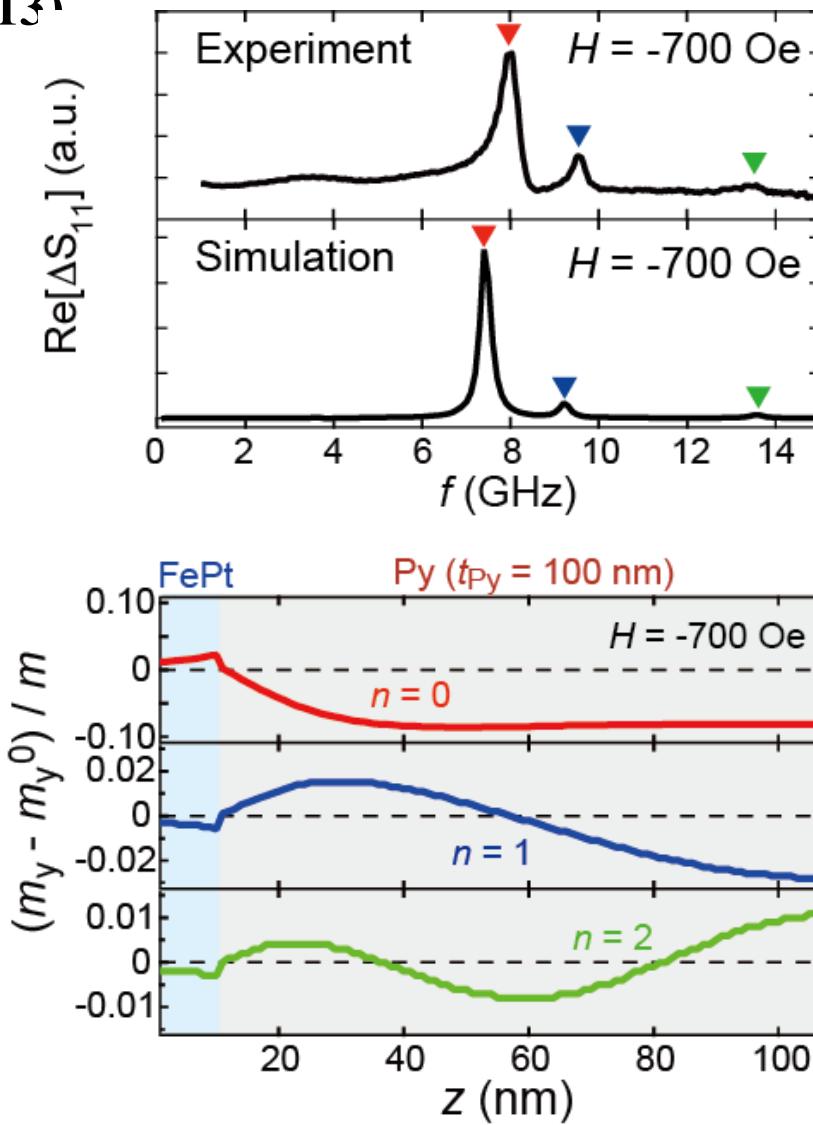
# Spin wave-assisted magnetization switching

T. Seki, KT, et al., *Nature Commun.*, 4:1726 doi: 10.1038/ncomm2737  
(2013)

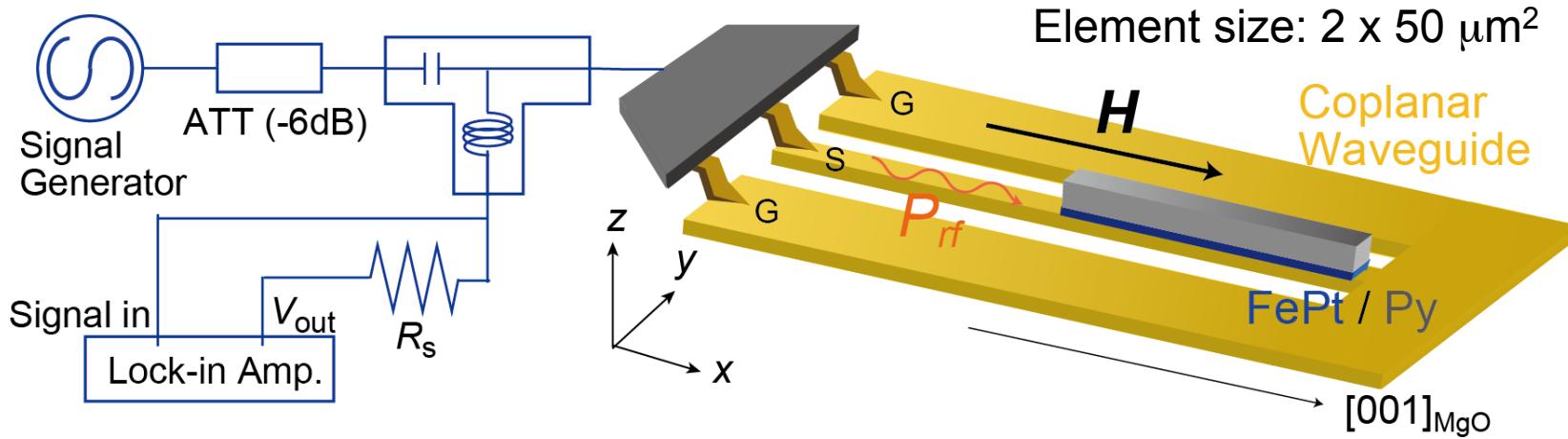
## FePt / Permalloy (Py) Exchange-Coupled Bilayer



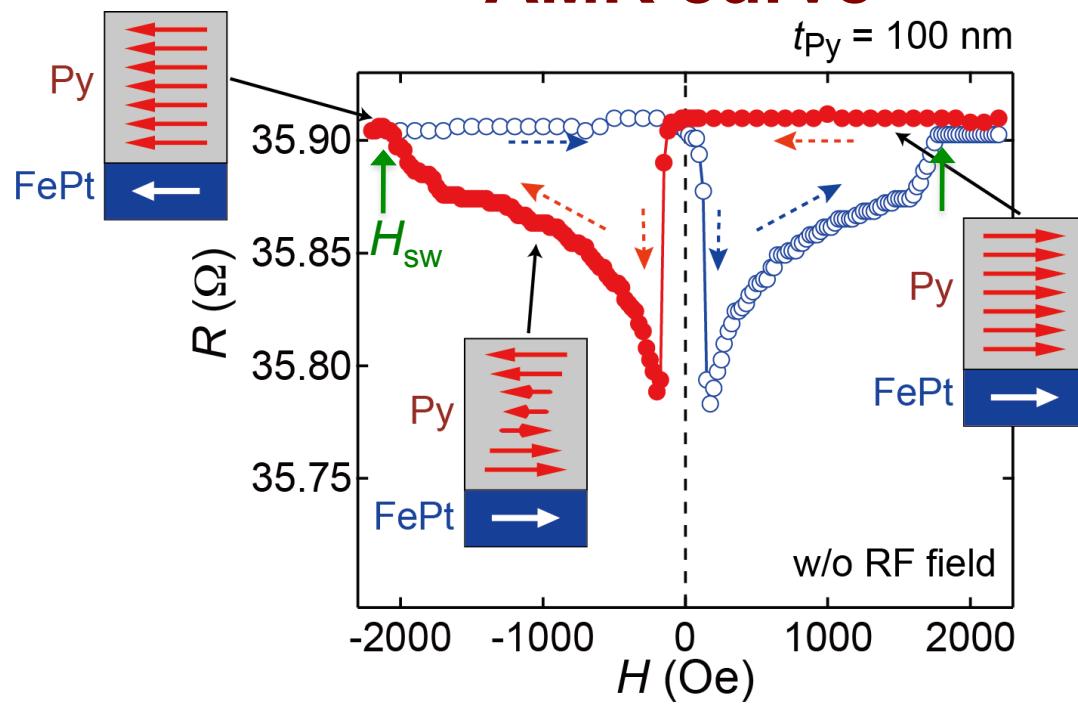
Utilization of Perpendicular Standing Spin Wave Mode in the Bilayer



# Spin wave-assisted magnetization switching



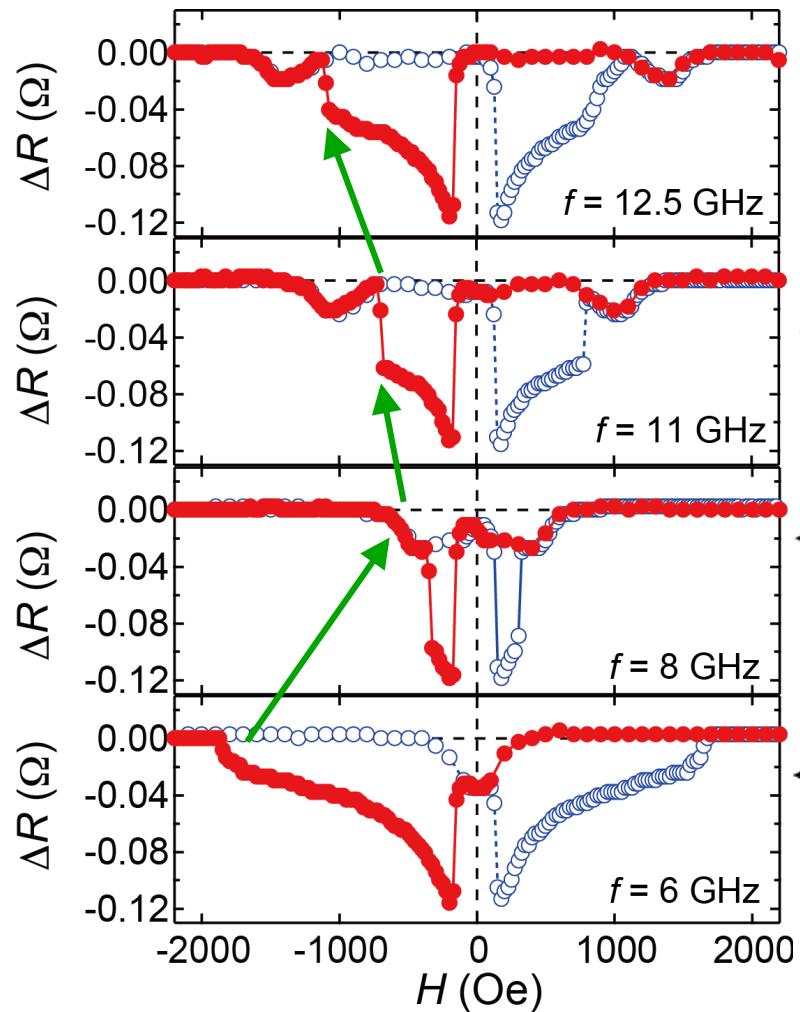
AMR curve



Without spin wave excitation,  
 $H_{\text{sw}} \sim 1900 \text{ Oe.}$

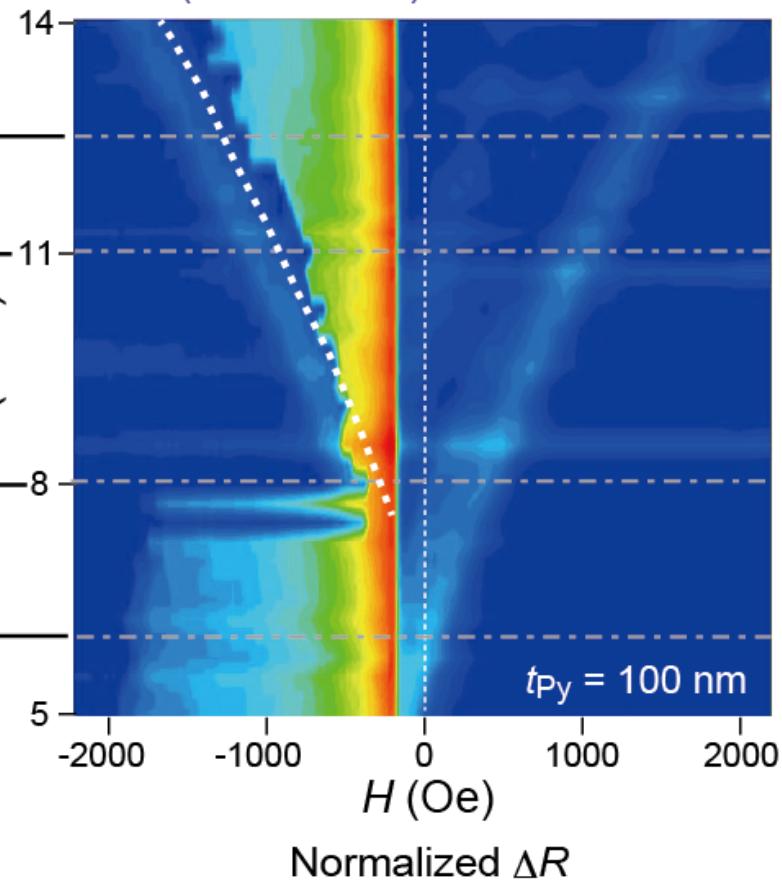
# Spin wave-assisted magnetization switching

$t_{\text{Py}} = 100 \text{ nm}$  ( $H_{\text{rf}} = 145 \text{ Oe}$ )



Field sweep: positive to negative

$n = 0$  (twisted state)



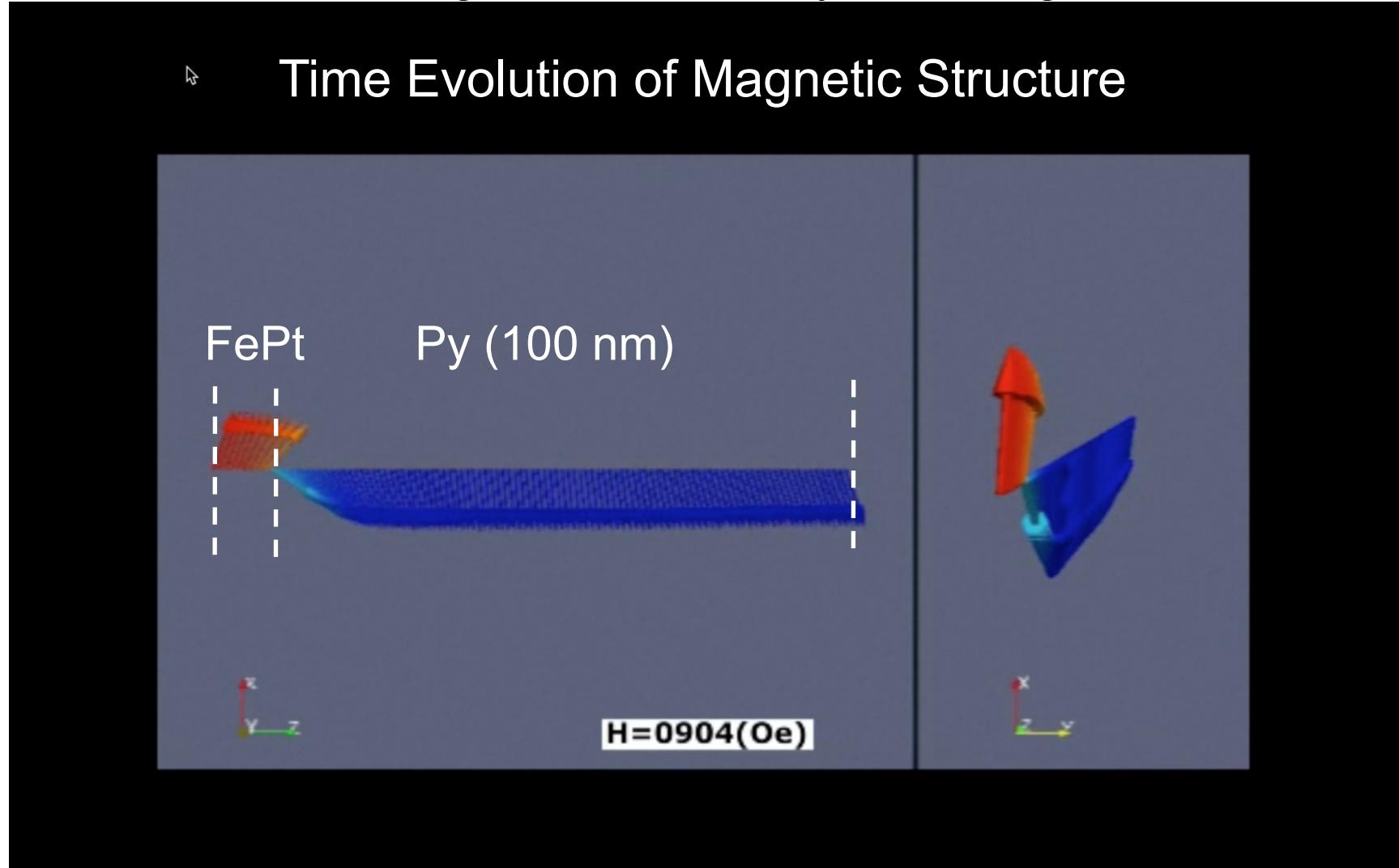
$t_{\text{Py}} = 100 \text{ nm}$

Normalized  $\Delta R$

-1 0

# Spin wave assisted magnetization switching

Time evolution of magnetic structure by micromagnetics simulation

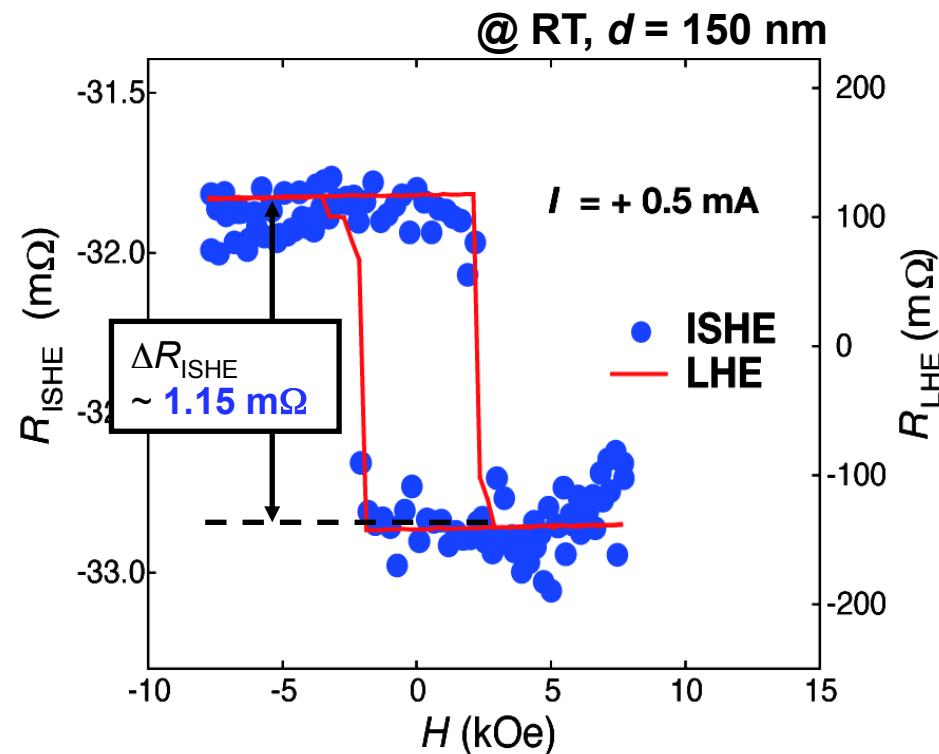
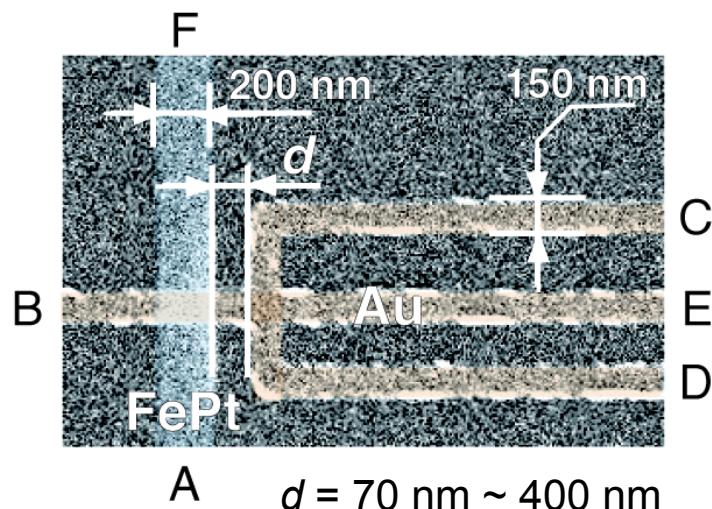
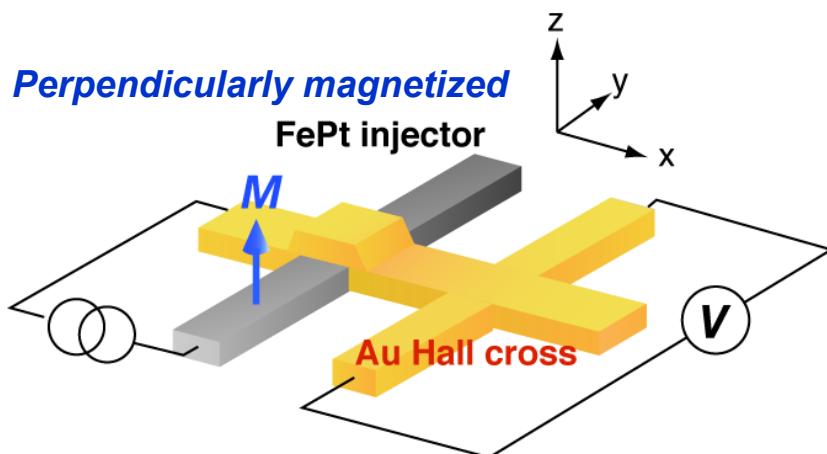


Magnetic Field Sweep: 50 Oe/nsec  
 $H_{rf} = 90$  Oe,  $f = 10$  GHz

by Y. Nozaki, Keio Univ.

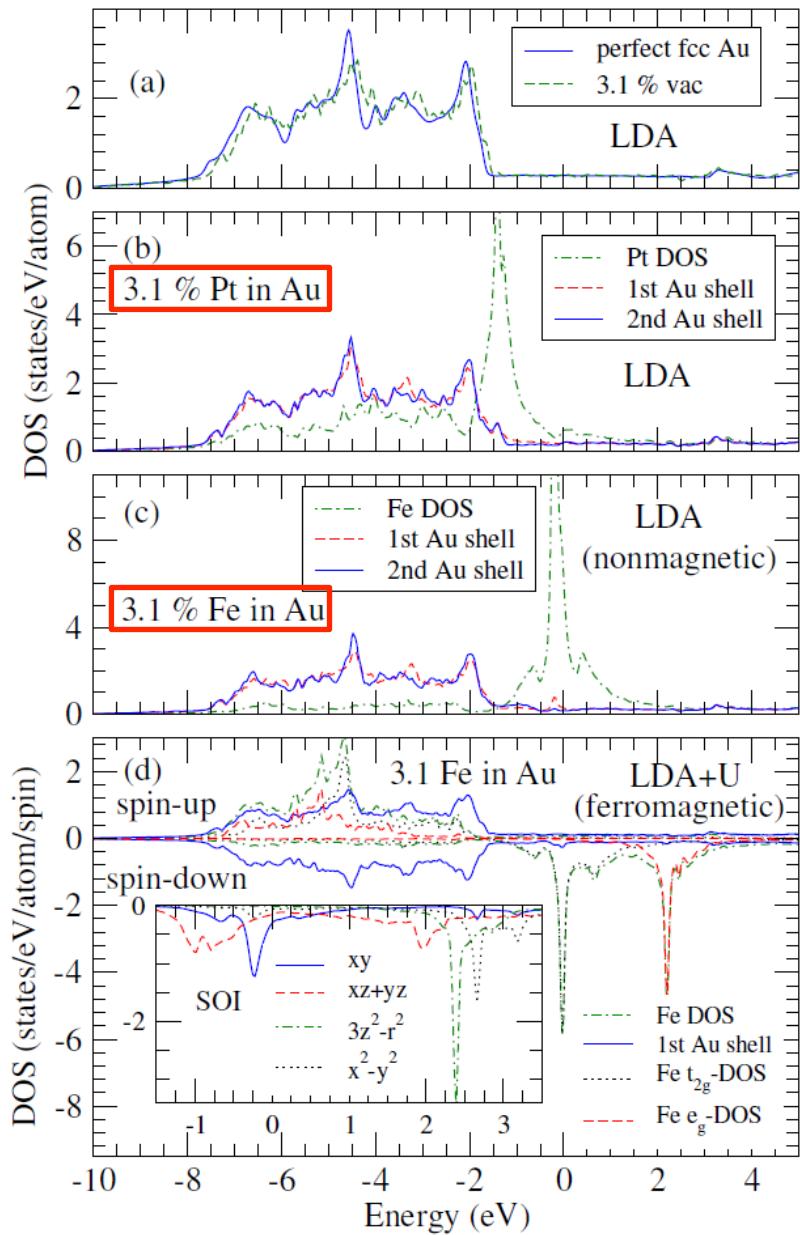
# Observation of giant spin Hall effect in perpendicularly magnetized FePt/Au devices

T. Seki, K. T. et al., *Nature Materials*, 7 (2008) 125.



Spin Hall angle  $\alpha_H \sim 0.1$   
Electrical detection of giant spin Hall effect at room temperature

# Theoretical discussion



G.Y. Guo, S. Maekawa, and N. Nagaosa  
Phys. Rev. Lett., 102 (2009) 036401.

## Spin Hall Effect by Kondo singlet state

### Orbital selective Kondo

e<sub>g</sub> Kondo limit  $\rightarrow T_K \approx 0.4K$   
t<sub>2g</sub> Mixed valence  $d^6$  and  $d^7$   
hybridization with Au s- and d-orbitals

### Renormalization effect due to electron correlation

$$\Delta = 1.4eV \Rightarrow \Delta^* = 0.3eV$$

$$10Dq = 0.1eV \Rightarrow 10Dq^* = 2.0eV$$

$$\lambda = 0.03eV \Rightarrow \lambda^* \approx 1eV$$

Resonant skew scattering  
→ Giant SHE

# Recent development on giant SHE

- Enhancement due to skew scattering by impurities

## Our study

Undoped Au :  $\alpha_H = 0.05$  (corrected by geometrical effect)

Fe-doped Au :  $\alpha_H = 0.05$

*I. Sugai, KT, et al., IEEE Trans Magn., 46 (2010) 2559.*

Pt-doped Au :  $\alpha_H = 0.11$       *Surface assisted skew scattering*

*B. Gu, KT, et al., Phys. Rev. Lett., 105 (2010) 216401.*

## Otani's group (Univ. Tokyo)

Ir-doped Cu :  $\alpha_H = 0.02$

*Y. Niimi et al., Phys. Rev. Lett., 106 (2011) 126601.*

Bi-doped Cu :  $\alpha_H = 0.24$

*Y. Niimi et al., Phys. Rev. Lett., 109 (2012) 156602.*

## Ralph's group (Cornell Univ.)

## *Mechanism?*

$\beta$ -Ta :  $\alpha_H = 0.15$       *L. Liu et al., Science, 336 (2012) 555.*

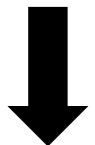
$\beta$ -W :  $\alpha_H = 0.33$       *C.-F. Pai et al., Appl. Phys. Lett., 101 (2012) 122404.*

## **$L1_0$ ordered alloy and element strategy**

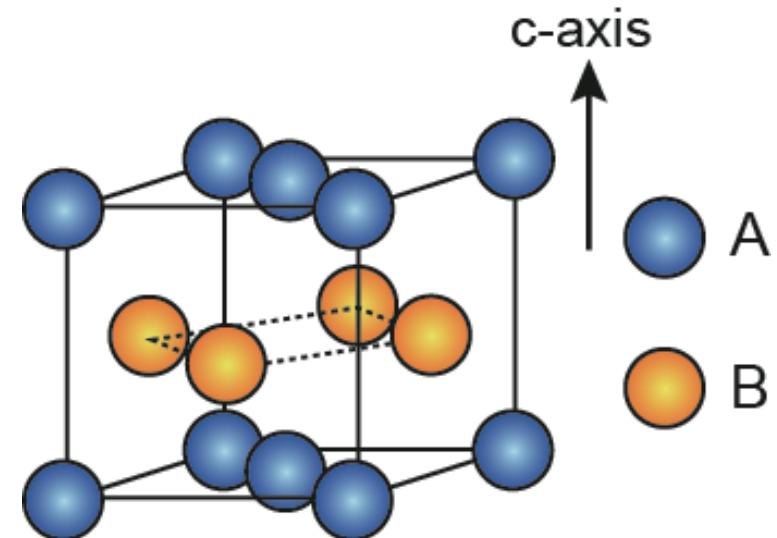
**FePt, FePd, CoPt, etc.**

**High uniaxial magnetic anisotropy**

$$K_u = 10^7 \sim 10^8 \text{ erg/cm}^3$$



**Spintronics  
Magnetic storages  
Permanent magnets**



**$L1_0$  ordered structure**

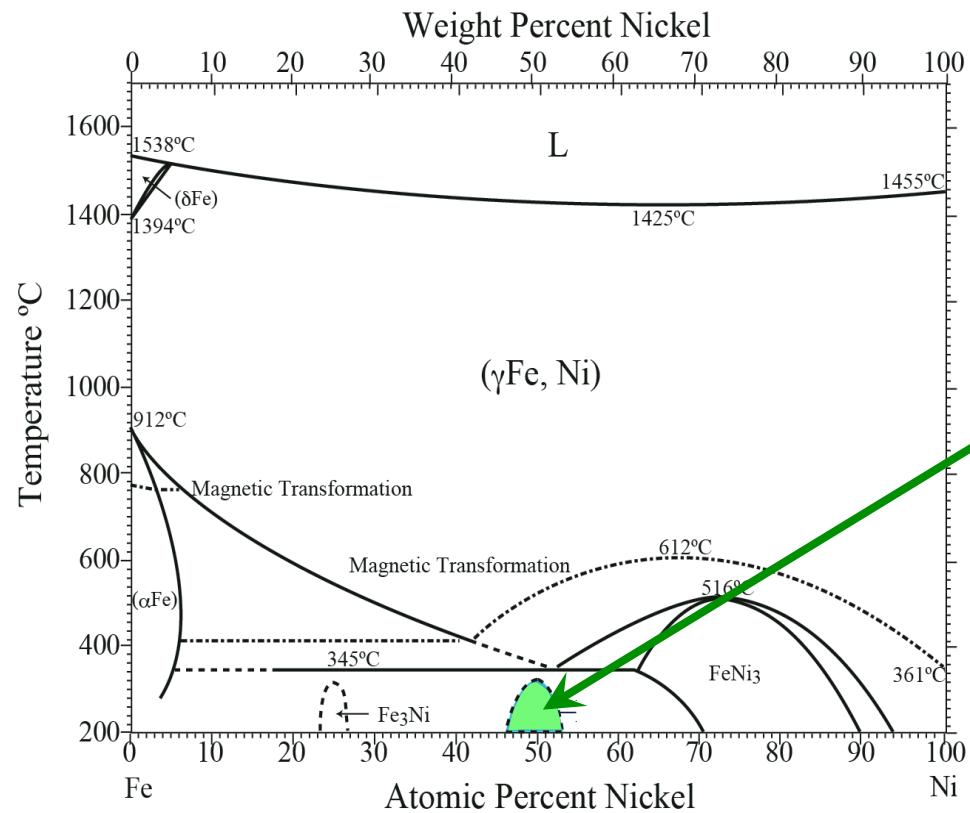
**However, a noble metal element is used in many cases!**



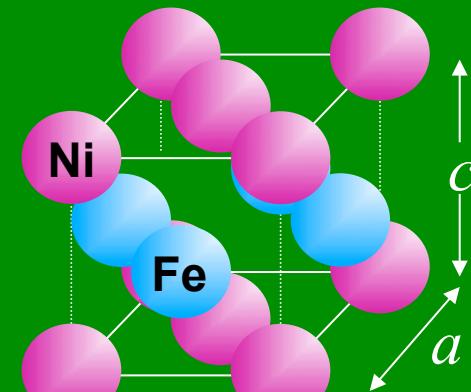
**Expensive  
High damping constant**

**→ Requirement for a noble-metal-free  $L1_0$  ordered alloy**

# $L1_0$ ordered FeNi alloy



Order-disorder transformation  
temperature  $\sim 320^\circ\text{C}$



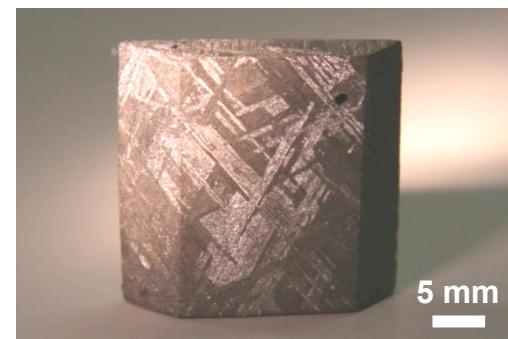
$$a \approx c = 3.582 \pm 0.002 \text{ \AA}$$

$L1_0$  ordered FeNi alloy

Requires annealing for an astronomically long time  
Naturally found only in meteorites

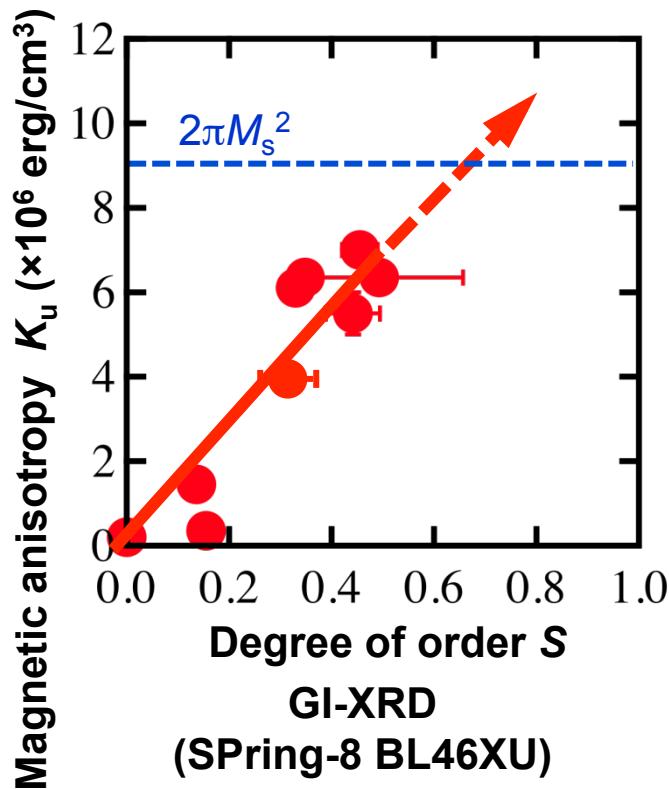
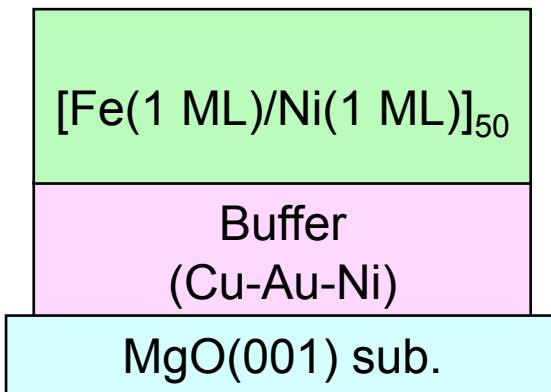
Neutron irradiation :  $K_u = 1.3 \times 10^7 \text{ erg/cm}^3$

J. Pauleve *et al.*, J. Appl. Phys. 39, 989 (1968).



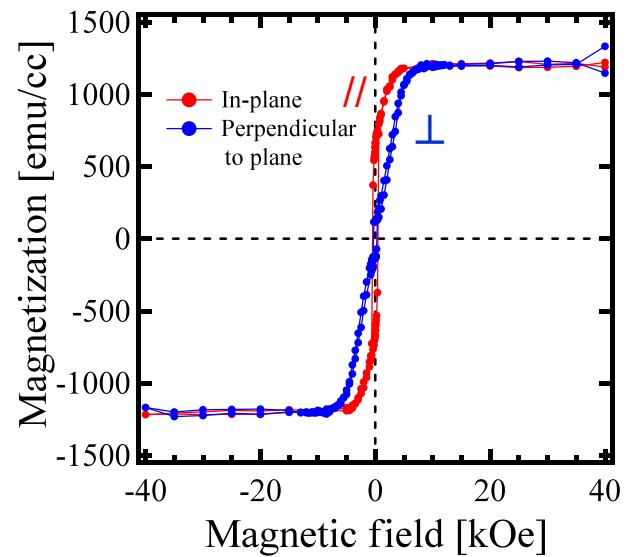
meteorite

# $L1_0$ -FeNi fabricated by alternate monatomic layer deposition



- Optimization of growth temperature
- Optimization of buffer

Lattice matching  
Surface flatness  
Nonmagnetic



$S = 0.5$   
 $K_u = 7 \times 10^6$  erg/cm $^3$   
*T. Kojima, KT, et al., JJAP, 52 (2012) 010204.*  
 $\alpha = 0.013$  ( $L1_0$ )  
 $0.009$  (disordered)  
*(in collaboration with Prof. Mizukami's group. unpublished)*

Target :  $S > 0.9$   
 $K_u > 10^7$  erg/cm $^3$   
(perpendicularly magnetized)

# Summary

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## *Spin current and spintronics*

- Recent progress of research on pure spin current

Spin Hall effect

Spin pumping

Spin Seebeck effect, etc.

- Materials for spintronics

Half-metallic Heusler alloys (Co<sub>2</sub>MnSi)

→ *Enhanced CPP-GMR*

High magnetic anisotropy  $L1_0$ -ordered alloys (FePt)

→ *Perpendicular spin polarizer*

*Magnetization switching*

*Noble metal free* → FeNi